

GW1NS series of FPGA Products

DataSheet

DS821-1.6.1E, 11/27/2020

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Revision History

Revision Thistory					
Date	Version	Description			
09/10/2018	1.0E	Initial version published (Preliminary).			
11/22/2018	1.1E	GW1NS-2C added.			
04/03/2019	1.2E	Operating conditions in Chapter 4 updated;			
10/16/2019	1.3E	 VCCX of UX devices is greater than or equals to VCCO; GW1NS-4C/4 added; B-SRAM of GW1NS-4C/4 does not support Dual Port mode; Description of Cortex-M3 updated. 			
11/12/2019	1.4E	 CS49 package info. added; Max. I/O updated; IODELAY description added. 			
03/18/2020	1.5E	 GW1NS-2 CS36U package info. added; ADC reference voltage added; GW1NS-LX2 VCCIO≤1.8V; The structure of 4 AC/DC Characteristic updated. The description of CLKIN updated. 			
07/29/2020	1.6E	GW1NS-4/4C MG64 package info. added.			
11/27/2020	1.6.1E	The Max. operating frequency of ARM Cortex-M3 updated.			

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1 About This Guide 1.1 Purpose

1 About This Guide

1.1 Purpose

This data sheet describes the features, product resources and structure, AC/DC characteristics, timing specifications of the configuration interface, and the ordering information of the GW1NS series of FPGA product. It is designed to help you understand the GW1NS series of FPGA products quickly and select and use devices appropriately.

1.2 Related Documents

The latest user guides are available on GOWINSEMI Website. You can find the related documents at www.gowinsemi.com:

- 1. DS821, GW1NS series of FPGA Products Data Sheet
- 2. <u>UG290, Gowin FPGA Products Programming and Configuration User</u> Guide
- 3. UG823, GW1NS series of FPGA Products Package and Pinout
- 4. UG822, GW1NS-2 Pinout
- 5. UG825, GW1NS-2C Pinout
- 6. UG824, GW1NS-4&4C Pinout

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1.3 Abbreviations and Terminology

The abbreviations and terminologies used in this manual are set out in Table 1-1 below.

Table 1-1 Abbreviations and Terminology

Abbreviations and Terminology	Name		
FPGA	Field Programmable Gate Array		
SoC	System On Chip		
ARM	Advanced RISC Machines		
AHB	Advanced High performance Bus		
APB	Advanced Peripheral Bus		
Timer	Timer		
UART	Universal Asynchronous Receiver/Transmitter		
NVIC	Nested Vector Interrupt Controller		
DAP	Debug Access Port		
Watchdog	Watchdog		
TimeStamp	TimeStamp		
DWT	Data Watchpoint Trace		
ITM	Instrumentation Trace Module		
TUIP	Trace Port Interface Unit		
USB	Universal Serial Bus		
PHY	Physical Layer		
ADC	Analog to Digital Converter		
SAR	Successive Approximation Register		
SFDR	Spurious-free Dynamic Range		
SINAD	Signal to Noise And Distortion		
LSB	Least Significant Bit		
INL	Integral Nonlinearity		
DNL	Differential Nonlinearity		
CFU	Configurable Function Unit		
CLS	Configurable Logic Slice		
CRU	Configurable Routing Unit		
LUT4	4-input Look-up Tables		
LUT5	5-input Look-up Tables		
LUT6	6-input Look-up Tables		
LUT7	7-input Look-up Tables		
LUT8	8-input Look-up Tables		
REG	Register		
ALU	Arithmetic Logic Unit		

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Abbreviations and Terminology	Name			
IOB	Input/Output Block			
S-SRAM	Shadow SRAM			
B-SRAM	Block SRAM			
SP	Single Port			
SDP	Semi Dual Port			
DP	Dual Port			
DQCE	Dynamic Quadrant Clock Enable			
DCS	Dynamic Clock Selector			
PLL	Phase-locked Loop			
GPIO	Gowin Programmable IO			
CS30	WLCSP30			
CS72	WLCSP72			
QN32	QFN32			
QN32U	QFN32U			
QN48	QFN48			
LQ100	LQFP100			
LQ144	LQFP144			
MG160	MBGA160			
PG204	PBGA204			
PG256	PBGA256			
UG332	UBGA332			
TDM	Time Division Multiplexing			
MG64	MBGA64			

1.4 Support and Feedback

Gowin Semiconductor provides customers with comprehensive technical support. If you have any questions, comments, or suggestions, please feel free to contact us directly using the information provided below.

Website: www.gowinsemi.com
E-mail: support@gowinsemi.com

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2 General Description 2.1 Features

2General Description

The GW1NS series of FPGA products are the first-generation products in the LittleBee® family and include GW1NS-2C/4C and GW1NS-2/4. GW1NS-2C/4C is embedded with an ARM Cortex-M3 hard core processor, while there is no ARM Cortex-M3 hard core processor in the GW1NS-2/4 device. In addition, t the GW1NS-2C/2 device is also embedded with USB2.0 PHY and ADC. When the ARM Cortex-M3 hard-core processor is employed as the core of the GW1NS-2C/4C device, the needs of the Min. memory can be met. FPGA logic resources and other embedded resources can flexibly facilitate the peripheral control functions, which provide excellent calculation functions and exceptional system response interrupts. They also offer high performance, low power consumption, a small number of pins, flexible usage, instant start-up, affordability, nonvolatile, high security, and abundant package types, among other benefits. The GW1NS-2C/4C device achieves seamless connection between programmable logic devices and embedded processors. They are compatible with multiple peripheral device standards and can, therefore, reduce costs of operation and be widely deployed in industrial control, communication, Internet of things, servo drive, consumption fields, etc.

GOWINSEMI provides a new generation of FPGA hardware development environment through market-oriented independent research and development that supports the GW1NS series of FPGA products and applies to FPGA synthesizing, layout, place and routing, data bitstream generation and download, etc.

2.1 Features

- Lower power consumption
 - 55nm embedded flash technology
 - Core voltage: 1.2V
 - GW1NS-2C/2 supports LX and UX
 - GW1NS-4C/4 supports LV
 - Clock dynamically turns on and off
- Hard core processor
 - Cortex-M3 32-bit RISC

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2 General Description 2.1 Features

- ARM3v7M architecture optimized for small-footprint embedded applications
- System timer (SysTick), providing a simple, 24-bit clear-on-write, decrementing, wrap-on-zero counter with a flexible control mechanism
- Thumb compatible, Thumb-2 instruction set processor core for high code density
- GW1NS-2C supports up to 30 MHz operation
- GW1NS-4C supports up to 80 MHz operation
- Hardware-division and single-cycle-multiplication
- Integrated nested vectored interrupt controller (NVIC) providing deterministic interrupt handling
- 26 interrupts with eight priority levels
- Memory protection unit (MPU), providing a privileged mode for protecting operation system functionality
- Unaligned data access, enabling data to be efficiently packed into memory
- Atomic bit manipulation (bit-banding), delivering maximum memory utilization and streamlined peripheral control
- Timer0 and Timer1
- UART0 and UART1
- Watchdog
- Debug port: JTAG and TPIU

USB2.0 PHY

- 480Mbps data speed, compatible with USB1.1 1.5/12Mbps data speed
- Plug and play
- Hot socket

ADC

- Eight channels
- 12-bit SAR AD conversion
- Slew Rate: 1MHz
- Dynamic range: >81 dB SFDR, >62 db SINAD
- Linear performance: INL<1 LSB, DNL<0.5 LSB, no missing codes

User Flash

- GW1NS-2C/2 is embedded with 128K Byte storage space
- GW1NS-4C/4 is embedded with 32K Byte storage space
- 32-bit data width

Multiple I/O Standards

- LVCMOS33/25/18/15/12; LVTTL33, SSTL33/25/18 I,
 SSTL33/25/18 II, SSTL15; HSTL18 I, HSTL18 II, HSTL15 I; PCI,
 LVDS25, RSDS, LVDS25E, BLVDSE
- MLVDSE, LVPECLE, RSDSE
- Input hysteresis option
- Supports 4mA,8mA,16mA,24mA,etc. drive options
- Slew Rate option
- Output drive strength option
- Individual Bus Keeper, Weak Pull-up, Weak Pull-down, and Open Drain option
- Hot Socket

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2 General Description 2.2 Product Resources

- BANK0 of GW1NS-2C/2 supports MIPI I/O input, and MIPI transmission speed can be up to 1.2Gbps
- BANK2 of GW1NS-2C/2 supports MIPI I/O output, and MIPI transmission speed can be up to 1.2Gbps
- BANK0 / BANK1 of GW1NS-4C/4 supports MIPI I/O input, and MIPI transmission speed can be up to 1.2Gbps
- BANK2 of GW1NS-4C/4 supports MIPI I/O output, and MIPI transmission speed can be up to 1.2Gbps
- BANK0 and BANK2 of GW1NS-2C/2 support I3C
- BANK0/BANK1/BANK2 of GW1NS-4C/4 support I3C
- Abundant Slices
 - Four input LUT (LUT4)
 - Double-edge flip-flops
 - Supports shifter register
- Block SRAM with multiple modes
 - Supports Dual Port, Single Port, and Semi Dual Port
 - Supports bytes write enable
- Flexible PLLs
 - Frequency adjustment (multiply and division) and phase adjustment
 - Supports global clock
- Built-in Flash programming
 - Instant-on
 - Supports security bit operation
 - Supports AUTO BOOT and DUAL BOOT
- Configuration
 - JTAG configuration
 - Supports on-chip DUAL BOOT configuration mode
 - Multiple GowinCONFIG configuration modes: AUTOBOOT, SSPI, MSPI, CPU, SERIAL

2.2 Product Resources

Table 2-1 Product Resources

Device	GW1NS-2	GW1NS-2C	GW1NS-4	GW1NS-4C
LUT4	1,728	1,728	4,608	4,608
Flip-Flop (FF)	1,296	1,296	3,456	3,456
Block SRAM B-SRAM(bits)	72K	72K	180K	180K
B-SRAM quantity B-SRAM	4	4	10	10
Multiplier (18 x 18 Multiplier)			16	16
User Flash (bits)	1M	1M	256K	256K
PLLs	1	1	2	2
OSC	1, ±5% accuracy	1, ±5% accuracy	1, ±5% accuracy	1, ±5% accuracy
Hard core processor ¹	-	Cortex-M3	-	Cortex-M3
USB PHY	USB 2.0 PHY	USB 2.0 PHY	-	-

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Device	GW1NS-2	GW1NS-2C	GW1NS-4	GW1NS-4C
ADC ²	1	1	-	-
Total number of I/O banks	4	4	4	4
Max. I/O	102	102	106	106
Core voltage	1.2V	1.2V	1.2V	1.2V

Note!

- [1]Please refer to 5.1Part Name, the device with the name including "C" before package type is embedded with hard core processor, and the device with the name not including "C" before package type does not support hard core processor;
- [2]Up to eight-channel ADC can be supported. For the detailed information, please refer to Table 2-2GW1NS-2C Package Information.

2.3 Package Information

Table 2-2 GW1NS-2C Package Information

Internal Resources	Package					
	CS36	CS36U	QN32	QN32U	QN48	LQ144
LUT4	Yes	Yes	Yes	Yes	Yes	Yes
FF	Yes	Yes	Yes	Yes	Yes	Yes
B-SRAM	Yes	Yes	Yes	Yes	Yes	Yes
User Flash	Yes	Yes	Yes	Yes	Yes	Yes
PLL	Yes	Yes	Yes	Yes	Yes	Yes
OSC	Yes	Yes	Yes	Yes	Yes	Yes
Cortex-M3	Yes	Yes	Yes	Yes	Yes	Yes
USB2.0 PHY	N/A	Yes	N/A	Yes	N/A	Yes
ADC ¹	4	4	N/A	2	8	8

Note!

[1] The Number refers to the number of channels supported by this package.

Table 2-3 GW1NS-2 Package Information

Internal Resources	Package					
	CS36	CS36U	QN32	QN32U	QN48	LQ144
LUT4	Yes	Yes	Yes	Yes	Yes	Yes
FF	Yes	Yes	Yes	Yes	Yes	Yes
B-SRAM	Yes	Yes	Yes	Yes	Yes	Yes
User Flash	Yes	Yes	Yes	Yes	Yes	Yes
PLL	Yes	Yes	Yes	Yes	Yes	Yes
OSC	Yes	Yes	Yes	Yes	Yes	Yes
USB2.0 PHY	N/A	N/A	N/A	Yes	N/A	Yes
ADC ¹	4	4	N/A	2	8	8

Note!

[1] The Number refers to the number of channels supported by this package.

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2 General Description 2.3 Package Information

Table 2-4 Max. I/O and LVDS Pair

Package	Pitch (mm)	Size (mm)	GW1NS-2C	GW1NS-2	GW1NS-4C	GW1NS-4
QN32	0.5	5 x 5	25(4)	25(4)	-	-
QN32U	0.5	5 x 5	16(2)	16(2)	-	-
CS36	0.4	2.5 x 2.5	30(6)	30(6)	-	-
CS36U	0.4	2.5 x 2.5	22(5)	22(5)	-	-
CS49	0.4	2.9 x 2.9	-	_	42(8)	42(8)
QN48	0.4	6 x 6	38(7)	38(7)	38(4)	38(4)
MG64	0.5	4.2 x 4.2	-	-	57(8)	57(8)
LQ144	0.5	20 x 20	95(12)	95(12)	-	-

Note!

- The JTAGSEL_N and JTAG pins cannot be used as I/O simultaneously. The data in this table is when the loaded four JTAG pins (TCK, TDI, TDO, and TMS) are used as I/O; When mode [2:0] = 001, JTAGSEL_N and the four JTAG pins (TCK, TDI, TDO, and TMS) can be used as GPIO simultaneously, and the Max. user I/O plus one. See DS821, GW1NS series of FPGA Products Data Sheet for more details;
- The package types in this data sheet are written with abbreviations. See 5.1Part Name.

Please refer to <u>UG822, GW1NS-2 Pinout, UG825, GW1NS-2C Pinout,</u> and <u>UG824, GW1NS-4&4C Pinout</u>.

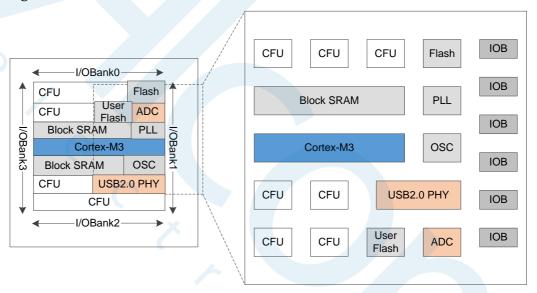
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3 Architecture Overview

3 Architecture

3.1 Architecture Overview

Figure 3-1 GW1NS-2 Architecture Overview



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3 Architecture _____ 3.1 Architecture Overview

Figure 3-2 GW1NS-2C Architecture Overview

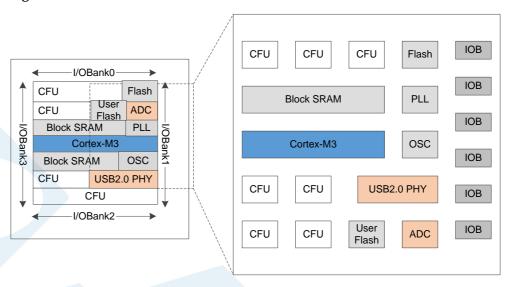


Figure 3-3 GW1NS-4 Architecture Overview

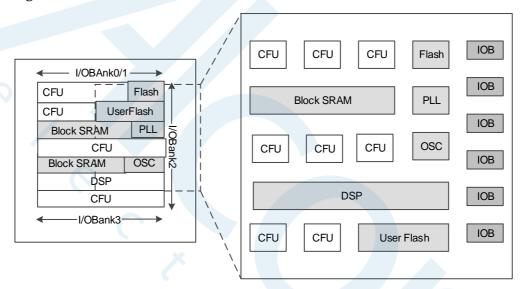
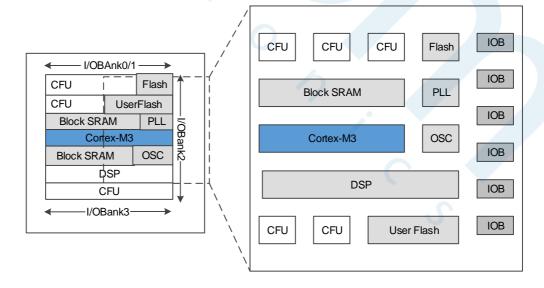


Figure 3-4 GW1NS-4C Architecture Overview



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3 Architecture 3.1 Architecture Overview

GW1NS series of FPGA products include CFU, B-SRAM, PLL, User Flash, on-chip oscillator, downloaded flash resources, USB2.0 PHY, and ADC. GW1NS-2C also includes Cortex-M3, See <u>Table 2-1</u> and <u>Table 2-2</u> for more detailed information.

The configurable function unit (CFU) is the base cell for the array of the GW1NS series of FPGA products. Devices with different capacities have different numbers of rows and columns. CFU can be configured as LUT4 mode and ALU mode, and Memory mode. For more detailed information, see 3.2 Configurable Function Unit.

The I/O resources in the GW1NS series of FPGA products are arranged around the periphery of the devices in groups referred to as banks, including Bank0, Bank1, Bank2, and Bank3. The I/O resources support multiple level standards, and support basic mode, SRD mode, and generic DDR mode. For more detailed information, see 3.3 IOB.

The B-SRAM is embedded as a row in the GW1NS series of FPGA products. In the FPGA array, each B-SRAM occupies three columns of CFU. B-SRAM has two usages; however, these cannot be employed simultaneously. One is for the Cortex-M3 processor SRAM, which is used for memory data read/write. The capacity of SRAM can be configured as 2K-Byte/4K-Byte/8K-Byte via Gowin YunYuan software. The unused B-SRAM can also be the FPGA storage resources. The other one usage is for user SRAM. One B-SRAM capacity is 18 Kbits. It supports multiple configuration modes and operation modes. For further details, please refer to 3.4Block SRAM (B-SRAM).

The User Flash is embedded in the GW1NS series of FPGA products, without loss of data even if powered off. The User Flash used in GW1NS-2/2C has three usages; however, these cannot be used simultaneously. One is used for Cortex-M3 processor ARM programs storage. In this way, the User Flash can only be read and cannot be written. One is used as the non-volatile memory resource. One is used for the DUAL BOOT mode of FPGA. See 3.5 User Flash (GW1NS-2C/2) for more detailed information. The User Flash used in GW1NS-4/4C has two usages and they cannot be used simultaneously. One is used for Cortex-M3 processor ARM programs storage. In this way, the User Flash can only be read and cannot be written. One is used as the non-volatile memory resource. See 3.6 User Flash (GW1NS-4C/4) for more detailed information.

GW1NS provides one PLL. PLL blocks provide the ability to synthesize clock frequencies. Frequency adjustment (multiply and division), phase adjustment, and duty cycle can be adjusted using the configuration of parameters. There is an internal programmable on-chip oscillator in each of the GW1NS series of the FPGA product. The on-chip oscillator supports the clock frequencies ranging from 2.5 MHz to 120MHz, providing the clock resource for the MSPI mode. It also provides clock resource for user designs with the clock precision reaching ±5%. For more detailed information, see 3.11 Clock.

The Flash resources embedded in the GW1NS series of FPGA

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products are used for built-in Flash programming, support instant start and security bit operation, and support AUTO BOOT and DUAL BOOT programming modes. For more detailed information, see <u>4.9 Configuration</u> Interface Timing Specification.

The Cortex-M3 hard-core processor is embedded in GW1NS-2C/4C. It supports 30 MHz program loading when the system starts up and supports higher speed data/instructions transmission. The AHB expansion bus facilitates communication with external storage devices. The APB bus also facilitates communication with external devices, such as UART. GPIO interfaces are convenient for communicating with the external interfaces. FPGA can be programmed to realize controller functions across different interfaces / standards, such as SPI, I²C, I³C, etc. For more detailed information, see3.8 Cortex-M3.

USB2.0 PHY is embedded in GW1NS-2C/2. FPGA logics can be programmed to realize USB controllers with specific functions. For more detailed information, see <u>3.9 USB2.0 PHY</u>.

An ADC is embedded in GW1NS-2C/2. It is a successive-approximation ADC with eight-channel data conversion, high dynamic performance, high precision, low power consumption, and low cost. For more detailed information, see <u>3.10 ADC</u>.

FPGA provides abundant CRUs, connecting all the resources in FPGA. For example, routing resources distributed in CFU and IOB connect resources in CFU and IOB. Routing resources can automatically be generated by Gowin software. In addition, the GW1NS series of FPGA Products also provide abundant GCLKs, long wires (LW), global set/reset (GSR), and programming options, etc. For more detailed information, see 3.11 Clock, 3.12 Long Wire (LW) and 3.13 Global Set/Reset (GSR).

3.2 Configurable Function Unit

The configurable function unit (CFU) is the base cell for the array of the GW1NS series of FPGA products. Each CFU consists of a configurable logic unit (CLU) and its routing resource configurable routing unit (CRU). In each CLU, there are four configurable logic slices (CLS). Each CLS contains look-up tables (LUT) and registers, as shown in Figure 3-5 below.

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Carry to Right CLU **CFU** CLU REG/ SREG LUT CLS3 REG/ LUT SREG LUT REG CLS₂ LUT REG CRU REG LUT CLS1 REG LUT LUT REG CLS₀ LUT REG Carry from left CLU

Figure 3-5 CFU Structure

Note!

SERG needs special patch supporting. Please contact Gowin technical support or local O ffice for this patch.

3.2.1 CLU

The CLU supports three operation modes: basic logic mode, ALU mode, and memory mode.

Basic Logic Mode

Each LUT can be configured as one four input LUT. A higher input number of LUT can be formed by combining LUT4 together.

- Each CLS can form one five input LUT5.
- Two CLSs can form one six input LUT6.
- Four CLSs can form one seven input LUT7.
- Eight CLSs (two CLUs) can form one eight input LUT8.

ALU Mode

When combined with carry chain logic, the LUT can be configured as the ALU mode to implement the following functions.

- Adder and subtractor
- Up/down counter
- Comparator, including greater-than, less-than, and not-equal-to
- MULT

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Register

There are two registers in each configurable logic slice (CLS0~CLS2), as shown in Figure 3-6 below.

Figure 3-6 Register in CLS

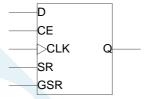


Table 3-1 Register Description in CFU

Signal	I/O	Description
D	I	Data input ¹
CE	I	CLK enable, can be high or low effective ²
CLK		Clock, can be rising edge or falling edge trigging ²
SR	ı	 Set/Reset, can be configured as ²: Synchronized reset Synchronized set Asynchronous reset Asynchronous set Non
GSR ^{3,4}	I	Global Set/Reset, can be configured as ⁴ : Asynchronous reset Asynchronous set Non
Q	0	Register

Note!

- [1] The source of the signal D can be the output of a LUT, or the input of the CRU; as such, the register can be used alone when LUTs are in use.
- [2] CE/CLK/SR in CFU is independent.
- [3] In the GW1NS series of FPGA products, GSR has its own dedicated network.
- [4] When both SR and GSR are effective, GSR has higher priority.

3.2.2 CRU

The main functions of the CRU are as follows:

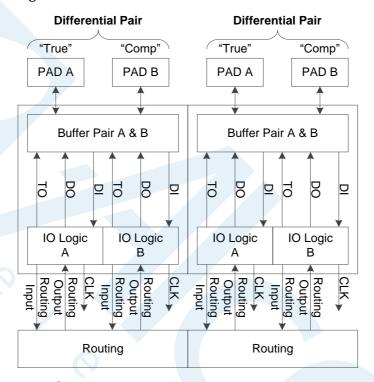
- Input selection: Select input signals for the CFU.
- Configurable routing: Connect the input and output of the CFUs, including inside the CFU, CFU to CFU, and CFU to other functional blocks in FPGA.

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3.3 **IOB**

The IOB in the GW1NS series of FPGA products includes IO buffer, IO logic, and its routing unit. As shown in Figure 3-7, each IOB connects to two pins (Marked A and B). They can be used as a differential pair or as two single-end input/output.

Figure 3-7 IOB Structure View



IOB Features:

- V_{CCO} supplied with each bank
- Supports multiple level standard: LVCMOS, PCI, LVTTL, LVDS, SSTL, and HSTL; BANK3 of GW1NS-4C/4 only supports single-end LVCMOS input/output and LVDS25E differential output
- Input hysteresis option
- Output drive strength option
- Slew rate option
- Individual Bus Keeper, Weak Pull-up, Weak Pull-down, and Open Drain option
- Hot socket, excluding BANK3 of GW1NS-4C/4
- IO logic supports basic mode, SRD mode, and generic DDR mode
- BANK0 of GW1NS-2C/2 supports MIPI input
- BANK2 of GW1NS-2C/2 supports MIPI output
- BANK0/BANK1 of GW1NS-4C/4 supports MIPI input
- BANK2 of GW1NS-4C/4 supports MIPI output
- BANK0 and BANK2 of GW1NS-2C/2 support I3C
- BANK0/BANK1/BANK2 of GW1NS-4C/4 support I3C

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3.3.1 I/O Buffer

There are four IO Banks in the GW1NS series of FPGA products, as shown in Figure 3-8. To support SSTL, HSTL, etc., each bank also provides one independent voltage source (V_{REF}) as referenced voltage. The user can choose from the internal reference voltage of the bank (0.5 x V_{CCO}) or the external reference voltage using any IO from the bank.

Figure 3-8 GW1NS-2C/2 I/O Bank Distribution

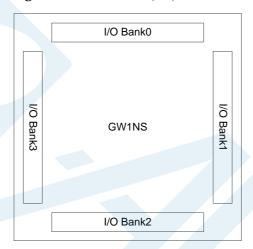
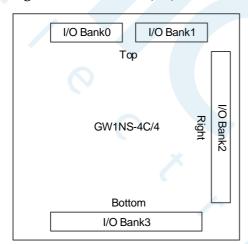


Figure 3-9 GW1NS-4C/4 I/O Bank Distribution



GW1NS-2C/2 supports LX and UX.

GW1NS-4C/4 supports LV.

The core voltage of the GW1NS series of FPGA products is 1.2V;

LX has no linear voltage regulator, and V_{CCX} needs to be set to 1.8V. The I/O Bank voltage V_{CCO} can be set as 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V according to requirements. Note that V_{CCX} needs to be greater than or equals to V_{CCO} .

UX has linear voltage regulator, and V_{CCX} needs to be set to 2.5 V. The I/O Bank voltage V_{CCO} can be set as 1.2 V, 1.5 V, 1.8 V, 2.5 V, or 3.3 V according to requirements.

Note!

For both LX and UX devices of GW1NS-2C/2, V_{CC00} needs to be set as 1.2 V when

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BANK0 is used as MIPI input, and $V_{\rm CCO2}$ needs to be set as 1.2 V when BANK2 is used as MIPI output. The MIPI output speed of LX devices can ony reach 60% of that of UX devices.

- For GW1NS-4C/4, V_{CCO0}/V_{CCO1} needs to be set as 1.2 V when BANK0/BANK1 is used as MIPI output, and V_{CCO2} needs to be set as 1.2 V when BANK2 is used as MIPI output. When V_{CCX} is set as 1.8V, the MIPI output speed of LX devices can ony reach 60% of that of UX devices when V_{CCX} is set as 2.5V/3.3V
- By default, the Gowin Programmable IO (GPIO) is tri-stated input weak pull-up.

For the V_{CCO} requirements of different I/O standards, see Table 3-2.

Table 3-2 Output I/O Standards and Configuration Options

I/O output standard	Single/Differ	Bank V _{CCO} (V)	Driver Strength (mA)
LVTTL33	Single end	3.3	4,8,12,16,24
LVCMOS33	Single end	3.3	4,8,12,16,24
LVCMOS25	Single end	2.5	4,8,12,16
LVCMOS18	Single end	1.8	4,8,12
LVCMOS15	Single end	1.5	4,8
LVCMOS12	Single end	1.2	4,8
SSTL25_I	Single end	2.5	8
SSTL25_II	Single end	2.5	8
SSTL33_I	Single end	3.3	8
SSTL33_II	Single end	3.3	8
SSTL18_I	Single end	1.8	8
SSTL18_II	Single end	1.8	8
SSTL15	Single end	1.5	8
HSTL18_I	Single end	1.8	8
HSTL18_II	Single end	1.8	8
HSTL15_I	Single end	1.5	8
PCI33	Single end	3.3	N/A
LVPECL33E	Differential	3.3	16
MVLDS25E	Differential	2.5	16
BLVDS25E	Differential	2.5	16
RSDS25E	Differential	2.5	8
LVDS25E	Differential	2.5	8
LVDS25	Differential	2.5/3.3	3.5/2.5/2/6
RSDS	Differential	2.5/3.3	2
MINILVDS	Differential	2.5/3.3	2
PPLVDS	Differential	2.5/3.3	3.5
SSTL15D	Differential	1.5	8
SSTL25D_I	Differential	2.5	8
SSTL25D_II	Differential	2.5	8
SSTL33D_I	Differential	3.3	8

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I/O output standard	Single/Differ	Bank V _{CCO} (V)	Driver Strength (mA)
SSTL33D_II	Differential	3.3	8
SSTL18D_I	Differential	1.8	8
SSTL18D_II	Differential	1.8	8
HSTL18D_I	Differential	1.8	8
HSTL18D_II	Differential	1.8	8
HSTL15D_I	Differential	1.5	8

Note!

BANK3 of GW1NS-4C/4 only supports single-end LVCMOS input/output and LVDS25E differential output.

Table 3-3 Input I/O Standards and Configuration Options

I/O Input Standard	Single/Differ	Bank V _{CCO} (V)	Hysteresis	Need V _{REF}
LVTTL33	Single end	1.5/1.8/2.5/3.3	Yes	No
LVCMOS33	Single end	1.5/1.8/2.5/3.3	Yes	No
LVCMOS25	Single end	1.5/1.8/2.5/3.3	Yes	No
LVCMOS18	Single end	1.5/1.8/2.5/3.3	Yes	No
LVCMOS15	Single end	1.2/1.5/1.8/2.5/3.3	Yes	No
LVCMOS12	Single end	1.2/1.5/1.8/2.5/3.3	Yes	No
SSTL15	Single end	1.5/1.8/2.5/3.3	No	Yes
SSTL25_I	Single end	2.5/3.3	No	Yes
SSTL25_II	Single end	2.5/3.3	No	Yes
SSTL33_I	Single end	3.3	No	Yes
SSTL33_II	Single end	3.3	No	Yes
SSTL18_I	Single end	1.8/2.5/3.3	No	Yes
SSTL18_II	Single end	1.8/2.5/3.3	No	Yes
HSTL18_I	Single end	1.8/2.5/3.3	No	Yes
HSTL18_II	Single end	1.8/2.5/3.3	No	Yes
HSTL15_I	Single end	1.5/1.8/2.5/3.3	No	Yes
PCI33	Single end	3.3	Yes	No
LVDS	Differential	2.5/3.3	No	No
RSDS	Differential	2.5/3.3	No	No
MINILVDS	Differential	2.5/3.3	No	No
PPLVDS	Differential	2.5/3.3	No	No
LVDS25E	Differential	2.5/3.3	No	No
MLVDS25E	Differential	2.5/3.3	No	No
BLVDS25E	Differential	2.5/3.3	No	No
RSDS25E	Differential	2.5/3.3	No V	No
LVPECL33	Differential	3.3	No	No
SSTL15D	Differential	1.5/1.8/2.5/3.3	No	No

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I/O Input Standard	Single/Differ	Bank V _{CCO} (V)	Hysteresis	Need V _{REF}
SSTL25D_I	Differential	2.5/3.3	No	No
SSTL25D_II	Differential	2.5/3.3	No	No
SSTL33D_I	Differential	3.3	No	No
SSTL33D_II	Differential	3.3	No	No
SSTL18D_I	Differential	1.8/2.5/3.3	No	No
SSTL18D_II	Differential	1.8/2.5/3.3	No	No
HSTL18D_I	Differential	1.8/2.5/3.3	No	No
HSTL18D_II	Differential	1.8/2.5/3.3	No	No
HSTL15D_I	Differential	1.5/1.8/2.5/3.3	No	No

Note!

BANK3 of GW1NS-4C/4 only supports single-end LVCMOS input.

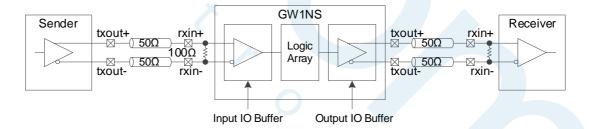
3.3.2 True LVDS Design

BANK1/2/3 in GW1NS-2/2C and BANK2 in GW1NS-4/4C support true LVDS output, but do not support internal 100 Ω input differential matched resistance. Bank0 in GW1NS-2/2C and BANK 0/1/3 in GW1NS-4/4C support internal 100 Ω input differential matched resistance, but do not support true LVDS output. BANK0/1/2/3 support LVDS25E, MLVDS25E, BLVDS25E, etc. For more detailed information about different levels, please refer to *UG289*, *Gowin Programmable IO User Guide*.

For more detailed information about true LVDS, please refer to <u>UG822</u>, <u>GW1NS-2&2C Pinout</u> and <u>UG824</u>, <u>GW1NS-4&4C Pinout</u>.

True LVDS input I/O needs external 100Ω terminal resistance for matching. See Figure 3-10for the true LVDS design.

Figure 3-10 True LVDS Design



For more detailed information about LVDS25E, MLVDS25E, and BLVDS25E on IO terminal matched resistance, please refer to <u>UG289</u>, <u>Gowin Programmable IO User Guide</u>.

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3.3.3 I/O Logic

Figure 3-11 shows the I/O logic output of the GW1NS series of FPGA products.

Figure 3-11 I/O Logic Input

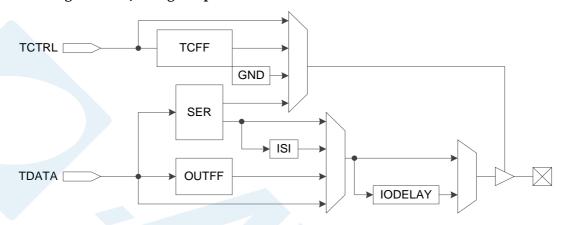
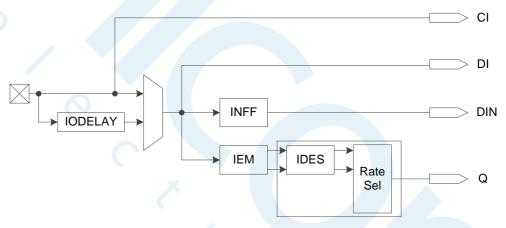


Figure 3-12 shows the I/O logic input of the GW1NS series of FPGA products.

Figure 3-12 I/O Logic Input



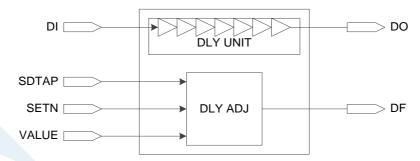
A description of the I/O logic modules of the GW1NS series FPGA products is presented below.

IODELAY

See Figure 3-13 for an overview of the IODELAY. Each I/O of the GW1NS series of FPGA products has an IODELAY cell. A total of 128(0~127) step delay is provided, with one-step delay time of about 30ps.

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Figure 3-13 IODELAY



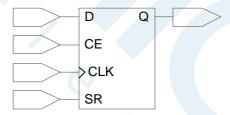
There are two ways to control the delay cell:

- Static control:
- Dynamic control: usually used to sample delay window together with IEM. The IODELAY cannot be used for both input and output at the same time

I/O Register

See Figure 3-14 for the I/O register in the GW1NS series of FPGA products. Each I/O provides one input register, INFF, one output register, OUTFF, and a tristate Register, TCFF.

Figure 3-14 Register Structure in I/O Logic



Note!

- CE can be either active ow (0: enable)or active high (1: enable).
- CLK can be either rising edge trigger or falling edge trigger.
- SR can be either synchronous/asynchronous SET or RESET or disable.
- The register can be programmed as register or latch.

IEM

IEM is for sampling clock edge and is used in the generic DDR mode. See Figure 3-15 for the IEM structure.

Figure 3-15 IEM Structure



De-serializer DES

The GW1NS series of FPGA products provide a simple Serializer SER for each output I/O to support advanced I/O protocols.

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Serializer SER

The GW1NS series of FPGA products provide a simple Serializer SER for each output I/O to support advanced I/O protocols.

3.3.4 I/O Logic Modes

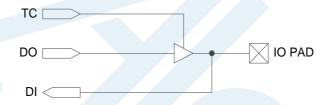
The I/O Logic in the GW1NS series of FPGA products supports several modes. In each operation, the I/O (or I/O differential pair) can be configured as output, input, and INOUT or tristate output (output signal with tristate control).

Not all the device pins support I/O logic. GW1NS-2 pins IOL6 (A, B, C.... J) do not support IO logic.

Basic Mode

In basic mode, the I/O Logic is as shown in Figure 3-16, and the TC, DO, and DI signals can connect to the internal cores directly through CRU.

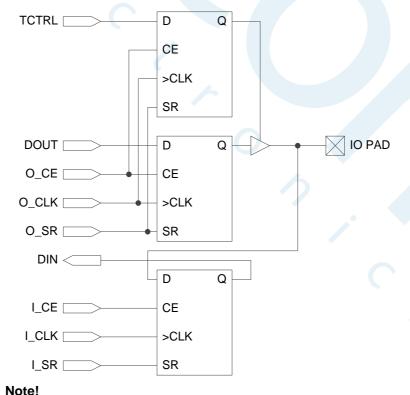
Figure 3-16 I/O Logic in Basic Mode



SDR Mode

In comparison with the basic mode, SDR utilizes the IO register, as shown in Figure 3-17. This can effectively improve IO timing.

Figure 3-17 I/O Logic in SDR Mode



NOLE

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- CLK enable O_CE and I_CE can be configured as active high or active low;
- O_CLK and I_CLK can be either rising edge trigger or falling edge trigger;
- Local set/reset signal O_SR and I_SR can be either Synchronized reset,Synchronized set, Asynchronous reset, Asynchronous set, or no-function;
- I/O in SDR mode can be configured as basic register or latch.

Generic DDR Mode

Higher speed IO protocols can be supported in generic DDR mode.

Figure 3-18 shows the generic DDR input, with a speed ratio of the internal logic to PAD 1:2.

Figure 3-18 I/O Logic in DDR Input Mode



Figure 3-19 shows generic DDR output, with a speed ratio of PAD to FPGA internal logic 2:1.

Figure 3-19 I/O Logic in DDR Output Mode



IDES4

In IDES4 mode, the speed ratio of the PAD to FPGA internal logic is 1:4.

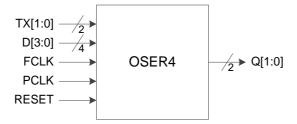
Figure 3-20 I/O Logic in IDES4 Mode



OSER4 Mode

In OSER4 mode, the speed ratio of the PAD to FPGA internal logic is 4:1.

Figure 3-21 I/O Logic in OSER4 Mode

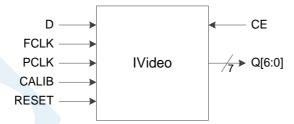


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IVideo Mode

In IVideo mode, the speed ratio of the PAD to FPGA internal logic is 1:7.

Figure 3-22 I/O Logic in IVideo Mode



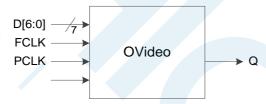
Note!

IVideo and IDES8/10 will occupy the neighboring I/O logic. If the I/O logic of a single port is occupied, the pin can only be programmed in SDR or BASIC mode.

OVideo Mode

In OVideo mode, the speed ratio of the PAD to FPGA internal logic is 7:1.

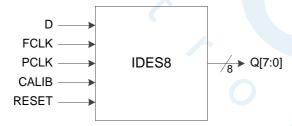
Figure 3-23 I/O Logic in OVideo Mode



IDES8 Mode

In IDES8 mode, the speed ratio of the PAD to FPGA internal logic is 1:8.

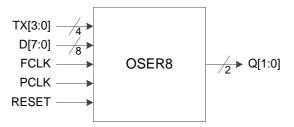
Figure 3-24 I/O Logic in IDES8 Mode



OSER8 Mode

In OSER8 mode, the speed ratio of the PAD to FPGA internal logic is 8:1.

Figure 3-25 I/O Logic in OSER8 Mode

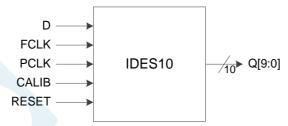


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IDES10 Mode

In IDES10 mode, the speed ratio of the PAD to FPGA internal logic is 1:10.

Figure 3-26 I/O Logic in IDES10 Mode



OSER10 Mode

In OSER10 mode, the speed ratio of the PAD to FPGA internal logic is 10:1.

Figure 3-27 I/O Logic in OSER10 Mode



IDES16 Mode

In IDES16 mode, the speed ratio of the PAD to FPGA internal logic is 1:16.

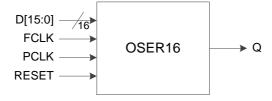
Figure 3-28 I/O Logic in IDES16 Mode



OSER16 Mode

In OSER16 mode, the speed ratio of the PAD to FPGA internal logic is 16:1.

Figure 3-29 I/O Logic in OSER16 Mode



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3.4 Block SRAM (B-SRAM)

3.4.1 Introduction

The GW1NS series of FPGA products provide abundant SRAM. The Block SRAM (B-SRAM) is embedded as a row in the FPGA array and is different from S-SRAM (Shadow SRAM). Each B-SRAM occupies three columns of CFU in the FPGA array.

B-SRAM supports two usages:

- Used for Cortex-M3 SRAM, providing high-speed read/write functions for Cortex-M3 to ensure system operation. One B-SRAM capacity is 16 Kbits (2K-Byte). The capacity of SRAM can be configured as 2K-Byte/4K-Byte/8K-Byte via Gowin YunYuan software. The unused B-SRAM can also be the FPGA storage resources.
- 2. Used for FPGA data storage. Each B-SRAM can be configured up to 18,432 bits (18Kbits). There are 5 operation modes: Single Port, Dual Port, Semi Dual Port, ROM, and FIFO. The signals and functional descriptions of B-SRAM are listed in Table 3-4.

An abundance of B-SRAM resources provide a guarantee for the user's high-performance design. B-SRAM features:

- Max.18,432 bits per B-SRAM
- B-SRAM itself can run at 190MHz at max
- Single Port
- Dual Port
- Semi Dual Port
- Parity bits
- ROM
- Data width from 1 to 36 bits
- Mixed clock mode
- Mixed data width mode
- Enable Byte operation for double byte or above
- Asynchronous reset, Synchronous reset
- Normal Read and Write Mode
- Read-before-write Mode
- Write-through Mode

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Port Name	I/O	Description
DIA	1	Port A data input
DIB	1	Port B data input
ADA		Port A address
ADB		Port B address
CEA		Clock enable, Port A
CEB		Clock enable, Port B
RESETA		Register reset, Port A
RESETB		Register reset, Port B
WREA I		Read/write enable, Port A
WREB	1	Read/write enable, Port B

Block select

Read/write cycle clock for Port A input registers

Read/write cycle clock for Port B input registers

Clock enable for Port A output registers

Clock enable for Port B output registers

Table 3-4 B-SRAM Signals

3.4.2 Configuration Mode

BLKSEL

CLKA

CLKB

OCEA

OCEB

DOA

DOB

The B-SRAM mode in the GW1NS series of FPGA products supports different data bus widths. See Table 3-5.

Port A data output

Port B data output

Table 3-5 Memory Size Configuration

1

Τ

ı

1

ı

0

0

Single Port Mode	Dual Port Mode	Semi-Dual Port Mode	Read Only
16K x 1	16K x 1	16K x 1	16K x 1
8K x 2	8K x 2	8K x 2	8K x 2
4K x 4	4K x 4	4K x 4	4K x 4
2K x 8	2K x 8	2K x 8	2K x 8
1K x 16	1K x 16	1K x 16	1K x 16
512 x 32	-	512 x 32	512 x 32
2K x 9	2K x 9	2K x 9	2K x 9
1K x 18	1K x 18	1K x 18	1K x 18
512 x 36	-	512 x 36	512 x 36

Note!

GW1NS-2C/2 and GW1NS-4C/4 do not support Dual Port mode.

Single Port Mode

In the single port mode, B-SRAM can write to or read from one port at one clock edge. During the write operation, the data can show up at the output of B-SRAM. NORMAL-WRITE MODE and Write—through Mode can be

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supported. When the output register is bypassed, the new data will show at the same write clock rising edge.

For further information about Single Port Block Memory ports and the related description, please refer to <u>SUG283E</u>, <u>Gowin Primitives User</u> <u>Guide</u> > 3 Memory.

Dual Port Mode

B-SRAM support dual port mode. The applicable operations are as follows:

- Two independent read
- Two independent write
- An independent read and an independent write at different clock frequencies

For further information about Dual Port Block Memory ports and the related description, please refer to <u>SUG283E</u>, <u>Gowin Primitives User Guide</u> > 3 Memory.

Semi-Dual Port Mode

Semi-Dual Port supports read and write at the same time on different ports, but it is not possible to write and read to the same port at the same time. The system only supports write on Port A, read on Port B.

For further information about Semi-Dual Port Block Memory ports and the related description, please refer to <u>SUG283E</u>, <u>Gowin Primitives User Guide</u> > 3 Memory.

Read Only

B-SRAM can be configured as ROM. The ROM can be initialized during the device configuration stage, and the ROM data needs to be provided in the initialization file. Initialization completes during the device power-on process.

Each B-SRAM can be configured as one 16 Kbits ROM. For further information about Read Only Port Block Memory ports and the related description, please refer to <u>SUG283E</u>, <u>Gowin Primitives User Guide</u> > 3 Memory.

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3.4.3 Mixed Data Bus Width Configuration

The B-SRAM in the GW1NS series of FPGA products supports mixed data bus width operation. In the dual port and semi-dual port modes, the data bus width for read and write can be different. For the configuration options that are available, please see Table 3-6 and Table 3-7 below.

Table 3-6 Dual Port Mixed Read/Write Data Width Configuration

Read	Write Por	Write Port											
Port	16K x 1	8K x 2	4K x 4	2K x 8	1K x 16	2K x 9	1K x 18						
16K x 1	Yes	Yes	Yes	Yes	Yes	N/A	N/A						
8K x 2	Yes	Yes	Yes	Yes	Yes	N/A	N/A						
4K x 4	Yes	Yes	Yes	Yes	Yes	N/A	N/A						
2K x 8	Yes	Yes	Yes	Yes	Yes	N/A	N/A						
1K x 16	Yes	Yes	Yes	Yes	Yes	N/A	N/A						
2K x 9	N/A	N/A	N/A	N/A	N/A	Yes	Yes						
1K x 18	N/A	N/A	N/A	N/A	N/A	Yes	Yes						

Note!

GW1NS-4C/4 does not support Dual Port mode.

Table 3-7 Semi Dual Port Mixed Read/Write Data Width Configuration

Read Port	Write Port												
Read Port	16K x 1	8K x 2	4K x 4	2K x 8	1K x 16	512 x 32	2K x 9	1K x 18	512 x 36				
16K x 1	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
8K x 2	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
4K x 4	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
2K x 8	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
1K x 16	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
512x32	Yes	Yes	Yes	Yes	Yes	Yes	N/A	N/A	N/A				
2K x 9	N/A	N/A	N/A	N/A	N/A	N/A	Yes	Yes	Yes				
1K x 18	N/A	N/A	N/A	N/A	N/A	N/A	Yes	Yes	Yes				

3.4.4 Byte-enable

The B-SRAM in the GW1NS series of FPGA products supports byte-enable. For data longer than a byte, the additional bits can be blocked, and only the selected portion can be written into. The blocked bits will be retained for future operation. Read/write enable ports (WREA, WREB), and byte-enable parameter options can be used to control the B-SRAM write operation.

3.4.5 Parity Bit

There are parity bits in B-SRAM. The 9th bit in each byte can be used as a parity bit or for data storage. However, the parity operation is not yet supported.

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3.4.6 Synchronous Operation

- All the input registers of B-SRAM support synchronous write;
- The output registers can be used as pipeline register to improve design performance;
- The output registers are bypass-able.

3.4.7 Power up Conditions

B-SRAM initialization is supported when powering up. During the power-up process, B-SRAM is in standby mode, and all the data outputs are "0". This also applies in ROM mode.

3.4.8 B-SRAM Operation Modes

B-SRAM supports five different operations, including two read operations (Bypass Mode and Pipeline Read Mode) and three write operations (Normal Write Mode, Write-through Mode, and Read-before-write Mode).

Read Mode

Read data from the B-SRAM via output registers or without using the registers.

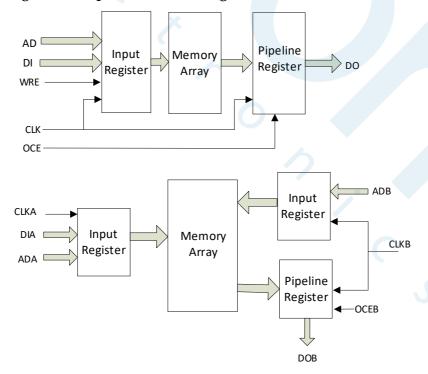
Pipeline Mode

While writing in the B-SRAM, the output register and pipeline register are also being written. The data bus can be up to 36 bits in this mode.

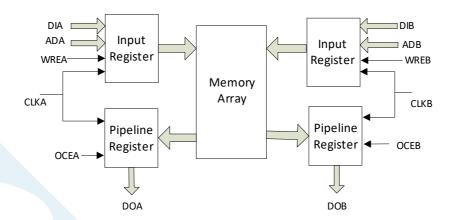
Bypass Mode

The output register is not used. The data is kept in the output of memory array.

Figure 3-30 Pipeline Mode in Single Port, Dual Port and Semi-Dual Port



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Write Mode

NORMAL WRITE MODE

In this mode, when the user writes data to one port, and the output data of this port does not change. The data written in will not appear at the read port.

WRITE-THROUGH MODE

In this mode, when the user writes data to one port, and the data written in will also appear at the output of this port.

READ-BEFORE-WRITE MODE

In this mode, when the user writes data to one port, and the data written in will be stored in the memory according to the address. The original data in this address will appear at the output of this port.

3.4.9 Clock Operations

Table 3-8 lists the clock operations in different B-SRAM modes:

Table 3-8 Clock Operations in Different B-SRAM Modes

Clock Operations	Dual Port Mode	Semi-Dual Port Mode	Single Port Mode
Independent Clock Mode	Yes	No	No
Read/Write Clock Mode	Yes	Yes	No
Single Port Clock Mode	No	No	Yes

Note!

GW1NS-4C/4 of GW1NS-2C/2 does not support Dual Port mode.

Independent Clock Mode

Figure 3-31 shows the independent clocks in dual port mode with each port with one clock. CLKA controls all the registers at Port A; CLKB controls all the registers at Port B.

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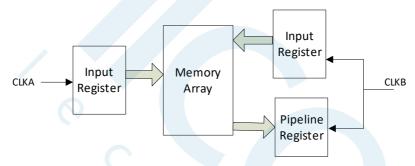
WREA WREB ADA í ADB Input Input DIA [DIB Register Register Memory Array CLKA CLKB Output Output DOB DOA Register Register WREA WREB

Figure 3-31 Independent Clock Mode

Read/Write Clock Operation

Figure 3-32 shows the read/write clock operations in the semi-dual port mode with one clock at each port. The write clock (CLKA) controls Port A data inputs, write address and read/write enable signals. The read clock (CLKB) controls Port B data output, read address, and read enable signals.

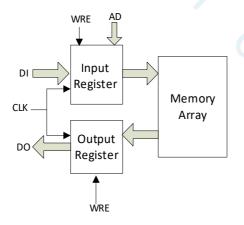
Figure 3-32 Read/Write Clock Mode



Single Port Clock Mode

Figure 3-33shows the clock operation in single port mode.

Figure 3-33 Single Port Clock Mode



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3.5 User Flash (GW1NS-2C/2)

3.5.1 Introduction

GW1NS-2C/2 offers 128 KB User Flash with the following three functions. The three functions cannot be used simultaneously

- Used for Cortex-M3 programming memory in the GW1NS-2C device. User Flash can only be read and does not support the other two functions:
- 2. Offers non-volatile memory for users in the GW1NS-2C and GW1NS devices and does not support the other two functions;
- 3. In DUAL BOOT mode of the GW1NS-2C and GW1NS devices, on-chip downloaded flash is the primary memory for data bitstream; user flash is used as the secondary memory for data bitstream; the user flash used for this function does not support the other two functions.

Main features are as follows:

- 32 bits data input/output
- Page architecture
 - 128 x 32 bits page size
 - 256 pages in total
- Fast read, write, and erase
 - Read access time 30ns
 - Write time 30us
 - Page erasure time 2ms
 - Macro erasure time 10ms
- Lower power consumption
 - IDLE 100uA
 - Read operation current 60 uA/MHz
 - Write operation current 2.4mA
 - Erase operation current 2.4 mA
- 100,000 write/erase cycles
- Minimum10 years data retention

3.5.2 Port Signal

See Figure 3-34 for GW1NS-2 User Flash.

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Figure 3-34 GW1NS-2 User Flash Ports

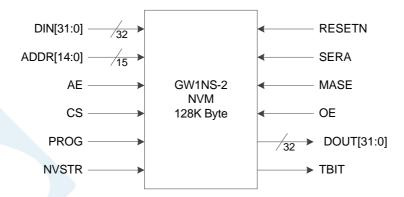


Table 3-9 Flash Module Signal Description

Pin name ¹	I/O	Description			
RESETN	I	Reset signal, active - low			
DIN[31:0]	I	Data input			
ADDR[14:0]	1	Address input			
AE	1	Address enable signals			
CS	1	Chip select			
PROG	1	Data enable signal			
NVSTR	1	Write signal			
SERA	1	Page erase signal			
MASE	1	Macro erase signal			
OE	1	Read enable			
DOUT[31:0]	0	Output data			
TBIT	0	Indicator of write/erase done			

Note!

[1] Port names of Control, address, and data signals.

3.5.3 Page Address Mapping

User flash capacity is 128KB. There are 256 pages in total, each of which has a page size of 512 bytes. Each page is divided into two lines, and each line includes 64 x 32 bits.

Table 3-10 User Data Flash Address Mapping

Page	Selection	n Addre	ess	Line Selection	32bits Data Column Selection				ion					
A14	A13	A12	A11	A10	A9	A8	A7	A6	A5	A4	А3	A2	A1	A0
X8	X7	X6	X5	X4	Х3	X2	X1	X0	Y5	Y4	Y3	Y2	Y1	Y0

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Table 3-11	User	Information	Flash	Address	Mapping

Page Selection Address								Line Selection	32bits Data Column Selection					
A14	A13	A12	A11	A10	A9	A8	A7	A6	A5	A4	А3	A2	A1	A0
0/1	0/1	0/1	0/1	0/1	0/1	0/1	X1	X0	Y5	Y4	Y3	Y2	Y1	Y0

3.5.4 Operation Mode

User can set control signals to select different operation modes, as shown in Table 3-12.

Table 3-12 Operation Modes

MODE	CS	AE	OE	PROG	SERA	MASE	DIN	DOUT	ADDR	NVSTR
IDLE	L	L	L	L	L	L	Χ	Z	X	X
Read	Н	R	Н	L	L	L	Χ	DOUT	ADDR	L
Write	Н	R	L	Н	L	L	DIN	Z	ADDR	Н
Page Erasure Mode	Н	R	L	L	Н	L	Х	Z	ADDR	Н
Macro erase	Н	R	L	L	L	Н	Χ	Z	ADDR	Н

3.5.5 Read Operation

The Flash read operation is similar to that of ROM. The following conditions need to be met to read data:

When the AE signal is pulled high and the address setup time is met (≥5ns), the address will be latched at the AE rising edge;

OE signal is pulled high, (≥1ns) data occurs at DOUT, and the data access time is 30ns.

3.5.6 Write Operation

Erase the memory you want to write before the write operation.

The Flash write operation (data 0) is similar to that of the SRAM write operation. During the write operation, AE, PROG, and NVSTR must be high. Prepare the written data and address in advance. When the setup time is met (≥5ns), the data and address will be latched at the AE rising edge. When the AE is high and the NVSTR rising edge hold time is greater than 10 ns, NVSTR becomes high, and the data is written into the memory. The write access time is 30us.

3.5.7 Erase Operation

User Flash supports page erase and macro erase. The page erase size is 512 bytes. The macro erase size is the entire user data memory. When SERA is high, page erasure is valid; when MASE is high, Macro erasure is valid.

Page erase: AE, SERA, and NVSTR must be high for page erasure. Prepare the erasure address in advance. When the setup time is met (≥5ns), the address will be latched at the AE rising edge. When AE is high, and NVSTR rising edge hold time is greater than 10ns, NVSTR becomes

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high, and the address memory is erased, and the data becomes 1. Macro erasure time is 2 ms.

Macro erase: AE, MASE, and NVSTR must be high for macro erasure. Prepare the erasure address in advance. When the setup time is met (≥5ns), the address will be latched at the AE rising edge. When AE is high, and NVSTR rising edge hold time is greater than 10ns, NVSTR becomes high, and the address memory is erased, and the data becomes 1. Macro erasure time is 2ms.

3.6 User Flash (GW1NS-4C/4)

3.6.1 Introduction

GW1NS-4C/4 offers 32 KB User Flash with the following two usages and they cannot be used simultaneously.

- One is used for Cortex-M3 processor ARM programs storage. In this way, the User Flash can only be read and cannot be written.
- One is used as the non-volatile memory resource.

The user Flash memory is composed of row memory and column memory. One row memory is composed of 64 column memories. The capacity of one column memory is 32 bits, and the capacity of one row memory is 64*32=2048 bits. Page erase is supported, and one page capacity is 2048 bytes, i.e., one page includes 8 rows. The features are shown below:

- 10,000 write cycles
- Greater than 10 years Data Retention at +85 ℃
- Data Width: 32
- Capacity: 128 rows x 64 columns x 32 = 256kbits
- Page Erase Capability: 2,048 bytes per page
- Fast Page Erasure/Word Programming Operation
- Clock frequency: 40 MHz
- Word Programming Time:≤16 µs
- Page Erasure Time:≤120 ms
- Electric current
 - Read current/duration:2.19 mA/25 ns (V_{CC}) & 0.5 mA/25 ns (V_{CCX})
 (MAX)
 - Program / Erase operation: 12/12 mA(MAX)

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3.6.2 Port Signal

See Figure 3-35 for GW1NS-4/4C user flash:

Figure 3-35 GW1NS-4/4C Flash Port Signal

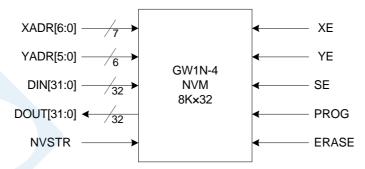


Table 3-13 Flash Module Signal Description

Pin name1	I/O	Description
XADR[5:0] ²	1	X address bus, used to access row address. XADR[n:3] is used to select one page; XADR[2:0] is used to select one row on one page. One page is composed of eight rows, and one row is composed of 64 columns. GW1N-2/2B/4/4B: 128 rows in all, n=6 GW1N-6/9: 304 rows in all, n=8
YADR[5:0] ²	ı	Y address bus, used to select one column within a row of memory block. One row consists of 64 columns.
DIN[31:0]	I	Data input bus.
DOUT[31:0]	0	Data output bus.
XE ²	1	X address enable signal, if XE is 0, all of row addresses are not enabled.
YE ²	I	Y address enable signal, if YE is 0, all of column addresses are not enabled.
SE ²	I	Detect amplifier enable signal, active high.
ERASE	I	Erase port, active-high.
PROG	1	Programming port, active-high.
NVSTR	I	Flash data storage port, active-high.

Note!

- [1] Port names of Control, address, and data signals.
- [2] The read operation is valid only if XE = YE = V_{CC} and SE meets the pulse timing requirements (T_{pws}, _{Tnws}). The address of read data is determined by XADR [5: 0] and YADR [5: 0].

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3.6.3 Operation Mode

Table 3-14 Truth Table in User Mode

Mode	XE	YE	SE	PROG	ERASE	NVSTR
Read Mode	Н	Н	Н	L	L	L
Programming Mode	Н	Н	L	Н	L	Н
Page Erasure Mode	Н	L	L	L	Н	Н

Note

3.7 **DSP**

3.7.1 Introduction

GW1N-4/4C device offers abundant DSP modules. Gowin DSP solutions can meet user demands for high performance digital signal processing design, such as FIR, FFT, etc. DSP blocks have the advantages of stable timing performance, high-usage, and low-power.

DSP offers the following functions:

- Multiplier with three widths: 9-bit, 18-bit, 36-bit
- 54-bit ALU
- Multipliers cascading to support wider data
- Barrel shifter
- Adaptive filtering through signal feedback
- Computing with options to round to a positive number or a prime number
- Supports pipeline mode and bypass mode.

Macro

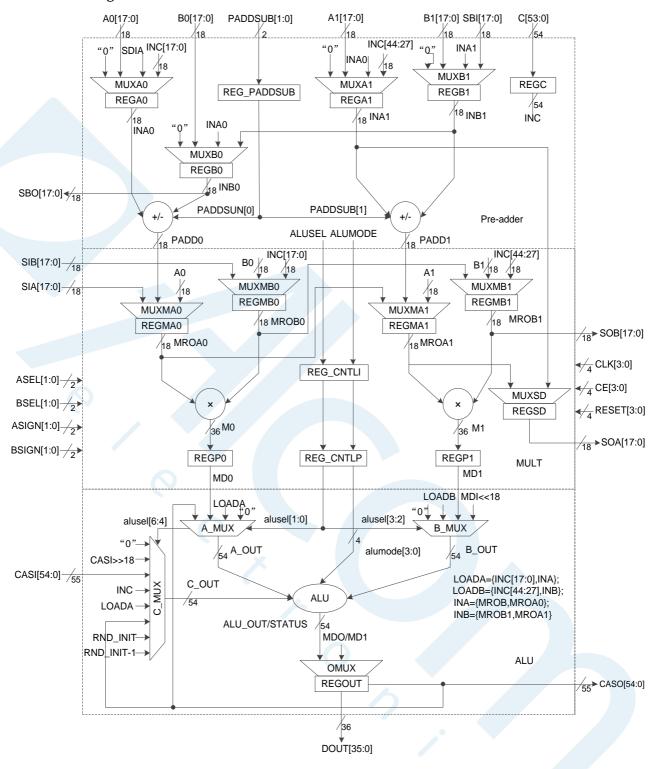
DSP blocks are embedded as rows in the FPGA array. Each DSP occupies nine CFU columns. Each DSP block contains two Macro, and each Macro contains two pre-adders, two 18 x 18 bit multipliers, and one three-input ALU.

Figure 3-36 shows the structure of one Macro.

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[&]quot;H" and "L" means high level and low level of VCC.

Figure 3-36 DSP Macro



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Table 3-15 shows DSP ports description.

Table 3-16 shows internal registers.

Table 3-15 DSP Ports Description

Port Name	I/O	Description
A0[17:0]	I	18-bit data input A0
B0[17:0]	I	18-bit data input B0
A1[17:0]	I	18-bit data input A1
B1[17:0]	I	18-bit data input B1
C[53:0]	I	54-bit data input C
SIA[17:0]		Shift data input A, used for CASCADE connection. The input signal SIA is directly connected to the output signal SOA of previously adjacent DSP and the delay from SIA to SOA inside a DSP is one clock cycle.
SIB[17:0]		Shift data input B, used for CASCADE connection. The input signal SIB is directly connected to the output signal SOB of previously adjacent DSP and the delay from SIB to SOB inside a DSP is one clock cycle.
SBI[17:0]	1	Pre - adder logic shift input, backward direction.
CASI[54:0]	1	ALU input from previous DSP block, used for cascade connection.
PADDSI0[1:0]	I /	Source select for Multiplier or pre-adder input A
BSEL[1:0]	I	Source select for Multiplier input B
ASIGN[1:0]	1	Sign bit for input A
BSIGN[1:0]	1	Sign bit for input B
PADDSUB[1:0]	1	Operation control signals of pre-adder, used for pre-adder logic add/subtract selection
CLK[3:0]	1	Clock input
CE[3:0]	1	Clock Enable
RESET[3:0]	1	Reset input, synchronous or asynchronous
SOA[17:0]	0	Shift data output A
SOB[17:0]	0	Shift data output B
SBO[17:0]	0	Pre - adder logic shift output, backward direction.
DOUT[35:0]	0	DSP output data
CASO[54:0]	0	ALU output to next DSP block for cascade connection, the highest bit is sign extended.

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Table 3-16 Internal Registers Description

Register	Description and Associated Attributes
A0 register	Registers for A0 input
A1 register	Registers for A1 input
B0 register	Registers for B0 input
B1 register	Registers for B1 input
C register	Registers for C input
P1_A0 register	Registers for A0 input of left multiplier
P1_A1 register	Registers for A1 input of right multiplier
P1_B0 register	Registers for B0 input of left multiplier
P1_B1 register	Registers for B1 input of right multiplier
P2_0 register	Registers for pipeline of left multiplier
P2_1 register	Registers for pipeline of right multiplier
OUT register	Registers for DOUT output
OPMODE register	Registers for operation mode control
SOA register	Registers for shift output at port SOA

PADD

Each DSP macro features two units of pre-adders to implement pre-add, pre-subtraction, and shifting.

PADD locates at the first stage with two inputs.,

- Parallel 18-bit input B or SBI;
- Parallel 18-bit input A or SIA.

Note!

Each input end supports pipeline mode and bypass mode.

GOWINSEMI PADD can be used as function block independently, which supports 9-bit and 18-bit width.

MULT

Multipliers locate after the pre-adder. Multipliers can be configured as 9×9 , 18×18 , 36×18 or 36×36 . Registered mode and bypass mode are supported both in input and output ports. The configuration modes that a macro supports include:

- One 18 x 36 multiplier
- Two 18 x 18 multipliers
- Four 9 x 9 multipliers

Note!

Two adjacent DSP macros can form a 36 x 36 multiplier.

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ALU

Each Macro has one 54 bits ALU54, which can further enhance MULT's functions. The registered and bypass mode are supported both in input and output ports. The functions are as following:

- Multiplier output data / 0, addition/subtraction operations for data A and data B;
- Multiplier output data / 0, addition/subtraction operations for data B and bit C:
- Addition/subtraction operations for data A, data B, and bit C;

3.7.2 DSP Operations

- Multiplier
- Accumulator
- MULTADDALU

3.8 Cortex-M3

3.8.1 Introduction

GW1NS-2C/4C is a system-on-chip FPGA device that incorporates a microprocessor system hard core, abundant logic resources, built-in user flash and B-SRAM resources, built-in PLL and OSC. Besides that, GW1NS-2C includes standard peripherals and featured hard cores, including USB2.0 PHY and ADC. The embedded microprocessor system contains a low-power, low-cost and high-performance ARM Cortex-M3 32-bit RISC. The flexible FPGA fabric serves as user programmable peripherals, or soft-core IPs.

The embedded microprocessor system consists of the processor block, with ARM Cortex-M3 32-bit RISC core and associated supporting bus system that connects to harden standard peripherals. The FPGA fabric contains a rich programmable logic resource called a Configured Functional Unit (CFU). This offers a flexible architecture that allows the user to employ peripherals with the microprocessor system. This can be achieved either by parameterized soft-core IPs or customized Verilog design to go through Gowin EDA Design Software from Synthesis, FPGA Place Rout to bit-file download into GW1NS-2. The microprosessor system only interfaces with the FPGA fabric and JTAG config-core internally with no access to the I/O Blocks of GW1NS-2.

The bus system consists of AHB-Lite Bus, AHB2APB Bridge, and two APB Bus: APB1 and APB2.

The microprocessor system relies on AHB bus to access FPGA side sub-memory system which has a pre-implemented sub-memory system controller for read-only-access 128 KB Flash-ROM and read/write-access 8 KB B-SRAM. Upon Power-On boot loading, Cortex-M3 loads instructions and data that are pre-stored in the Flash-ROM, and transfers it to the B-SRAM before initiating the execution.

In addition, there are two AHB bus extension ports: INTEXP0 and TARGEXP0. Each of these AHB extension ports provides a 32 bits AHB

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bus interconnecting to any high-speed User programmable peripherals implemented within the FPGA. A GPIO block interconnects the AHB bus with the FPGA fabric to allow the user to implement general purpose I/O functions in FPGA.

In terms of the two APB Bus (APB1 and APB2), APB1 interconnects with two timers (Timer0 and Timer1), two UARTs (Uart0 and Uart1), and one watchdog. Two UARTs connect to the FPGA directly. The two timers and the watchdog are controlled and used within the microprocessor system and are accessed through REG. The APB2 bus connects directly to the FPGA.

The processor block consists of Cortex-M3 core, bus matrix, Nested Vector Interrupt Controller (NVIC), Debug Access Port (DAP), and time stamp.

The Cortex-M3 core relies on the bus-matrix to access its supporting bus system (AHB-Lite Bus, AHB2APB Bridge, and two APB Bus: APB1 and APB2).

NVIC of GW1NS-2C offers two external user defined interrupts. NVIC of GW1NS-4C offers six external user defined interrupts. The DAP contains JTAG DAP and also Trace-Port-Interface-Unit (TPIU).

The Microprocessor System also provides an interrupt monitor signal, which combines GPIO interrupts as well as APB1 peripherals (UART0, UART1, Timer0, Timer1, Watchdog) interrupts, back to the FPGA fabric to report the current run-time interrupt Status of the Microprocessor System.

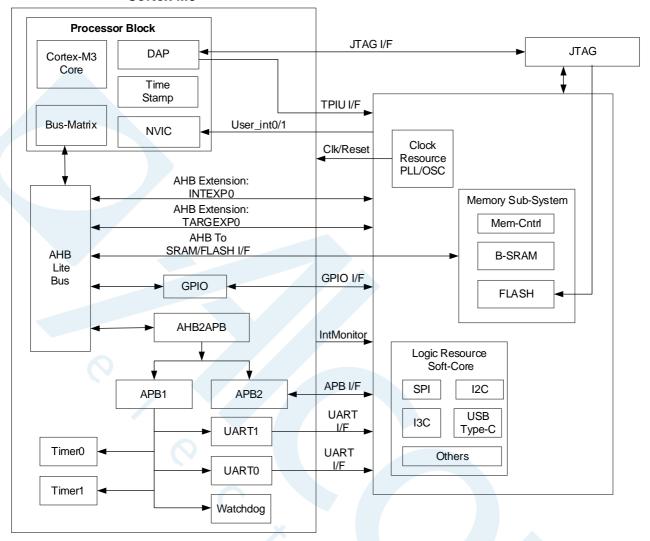
FPGA fabric takes advantage of its rich Clocking Resource (PLL, OSC) and provides the Main Clock, Power-On Reset and System Reset signals to the embedded microprocessor system.

See Figure 3-37 for the Cortex-M3 architecture.

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Figure 3-37 Cortex-M3 Architecture

Cortex-M3



3.8.2 Cortex-M3

Features of the microprocessor system embedded in GW1NS-2C are as follows:

- Compact core
- Thumb-2 instruction set, delivering the high-performance expected of an ARM core in the memory size usually
- Associated with 8 bits and 16 bits devices; typically, in the range of a few kilobytes of memory for microcontroller class applications
- Rapid application execution through Harvard architecture characterized by separate buses for instruction and data
- Achieves exceptional interrupt handling, by implementing the register manipulations required for handling an interrupt in hardware.
- Deterministic, fast interrupt processing.
- Memory protection unit (MPU), providing a privileged mode for protecting operation system functionality
- Migration from the ARM7[™] processor family for better performance and power efficiency

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- Full-featured debug solution
 - JTAG Debug Port (JTAG)
 - Flash Patch and Breakpoint (FPB) unit for implementing breakpoints
 - Data Watchpoint and Trigger (DWT) unit for implementing watchpoints, trigger resources, and system profiling
 - Instrumentation Trace Macrocell (ITM) for support of print style debugging
 - Trace Port Interface Unit (TPIU) for bridging to a Trace Port Analyzer

3.8.3 Bus-Matrix

The bus-matrix is used to connect the Cortex-M3 processor and debug port with an external AHB bus. Connections between bus-matrix and AHB bus:

- ICode bus: 32bit AHBLite bus, used for fetching instructions and vectors from code space;
- DCode bus: 32bit AHBLite bus, used for data loading/storage and debug access;
- System bus: 32bit AHBLite bus, used for fetching instructions and vectors from system space, data loading/storage and debug access;
- APB: 32bit APB bus, used for external space data loading/storage and debug access.

The bus-matrix controls the following functions as below:

- Unaligned accesses: Converts the unaligned processor access to aligned access;
- Bit-banding: converts the alias access of Bit_band to Bit_band space access:
- Write buffer: Bus-matrix contains one write-buffer, ensuring that the processor core is not affected by bus delay.

3.8.4 **NVIC**

NVIC features:

- Supports low-latency interrupt processing up to 26 interrupts
- GW1NS-2C supports two external user defined interrupts
- GW1NS-4C supports six external user defined interrupts
- A programmable priority level of 0-7 for each interrupt, A higher level corresponds to a lower priority; as such level 0 is the highest interrupt priority
- Low-latency exception and interrupt handling
- Dynamic reprioritization of interrupts
- The processor automatically stacks its state on exception entry and unstacks this state on exception exit, with no instruction overhead.

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Table 3-17 NVIC Address Table

Address	Name	Туре	Description
0x0000000	_StackTop	Read only	Top of stack interrupt
0x00000004	Reset_Handler	Read only	Reset interrupt
0x00000008	NMI_Handler	Read only	NMI interrupt
0x000000C	HardFault_Handler	Read only	Hard fault interrupt
0x0000010	MemMange_Handler	Read only	MPU fault interrupt
0x0000014	BusFault_Handler	Read/Write	Bus fault interrupt
0x0000018	UsageFault_Handler	Read only	Usage fault interrupt
0x0000002C	SVC_Handler	Read/Write	SVCall interrupt
0x0000030	DebugMon_Handler	Read only	Debug monitor interrupt
0x00000038	PendSV_Handler	Read / Write / Read only	Pending interrupt
0x000003C	SysTick_Handler	Read/Write	System timer interrupt
External interrupt (G	GW1NS-2C)		
0x00000040	UART0_Handler	Read/Write	UART0 reception and sending interrupt
0x00000048	UART1_Handler	Read/Write	UART1 reception and sending interrupt
0x00000058	PORT0_COMB_Handler	Read/Write	GPIO0 interrupt
0x00000060	TIMER0_Handler	Read/Write	TIMER0 interrupt
0x00000064	TIMER1_Handler	Read/Write	TIMER1 interrupt
0x00000070	UARTOVF_Handler	Read/Write	UART0/UART1 overflow interrupt
0x00000074	USER_INT0	Read/Write	User defined interrupt 0
0x00000078	USER_INT1	Read/Write	User defined interrupt 1
External interrupt (G	GW1NS-4C)		
0x00000040	UART0_Handler	Read/Write	UART0 reception and sending interrupt
0x00000044	USER_INT0_Handler	Read/Write	User defined interrupt 0
0x00000048	UART1_Handler	Read/Write	UART1 reception and sending interrupt
0x0000004C	USER_INT1_Handler	Read/Write	User defined interrupt 1
0x00000050	USER_INT2_Handler	Read/Write	User defined interrupt 2
0x00000058	PORT0_COMB_Handler	Read/Write	GPIO0 interrupt
0x0000005C	USER_INT3_Handler	Read/Write	User defined interrupt 3
0x00000060	TIMER0_Handler	Read/Write	TIMER0 interrupt
0x00000064	TIMER1_Handler	Read/Write	TIMER1 interrupt
0x0000006C	I2C_Handler	Read/Write	I2C interrupt
0x00000070	UARTOVF_Handler	Read/Write	UART0/UART1 overflow interrupt
0x00000074	USER_INT4_Handler	Read/Write	User defined interrupt 4

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Address	Name	Туре	Description
0x00000078	USER_INT5_Handler	Read/Write	User defined interrupt 5
External interrupt (G	W1NS-2C/4C)		
0x00000080	PORT0_0_Handler	Read/Write	GPIO0 Pin 0 interrupt
0x00000084	PORT0_1_Handler	Read/Write	GPIO0 Pin 1 interrupt
0x00000088	PORT0_2_Handler	Read/Write	GPIO0 Pin 2 interrupt
0x0000008C	PORT0_3_Handler	Read/Write	GPIO0 Pin 3 interrupt
0x00000090	PORT0_4_Handler	Read/Write	GPIO0 Pin 4 interrupt
0x00000094	PORT0_5_Handler	Read/Write	GPIO0 Pin 5 interrupt
0x00000098	PORT0_6_Handler	Read/Write	GPIO0 Pin 6 interrupt
0x0000009C	PORT0_7_Handler	Read/Write	GPIO0 Pin 7 interrupt
0x000000A0	PORT0_8_Handler	Read/Write	GPIO0 Pin 8 interrupt
0x000000A4	PORT0_9_Handler	Read/Write	GPIO0 Pin 9 interrupt
0x000000A8	PORT0_10_Handler	Read/Write	GPIO0 Pin 10 interrupt
0x000000AC	PORT0_11_Handler	Read/Write	GPIO0 Pin 11 interrupt
0x000000B0	PORT0_12_Handler	Read/Write	GPIO0 Pin 12 interrupt
0x000000B4	PORT0_13_Handler	Read/Write	GPIO0 Pin 13 interrupt
0x000000B8	PORT0_14_Handler	Read/Write	GPIO0 Pin 14 interrupt
0x000000BC	PORT0_15_Handler	Read/Write	GPIO0 Pin 15 interrupt

3.8.5 Boot Loader

The boot loader loads the initial stack pointer value from the program memory, and branches to the reset handler that the reset vector specifies in the program memory.

The current boot loader is based on UART Message Monitor which is easy to interface as a communication port with PC host. Below is an example of how to deploy the boot loader:

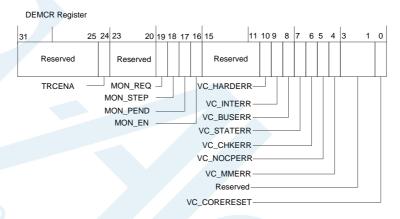
- Power-on reset to enter the reset handler to call the boot loader;
- Setup UART0 registers, such as BAUDIV and CTRL, to program the appropriate TX speed rate for the send and receive function;
- Begin Flash loader subroutine execution such as memory test, timer0, and timer1 tests etc;
- Write a 0x4 character (EOP) to terminate the program.

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3.8.6 TimeStamp

A 48 bits timestamp counter is included and connected to the ITM. It is clock gated and enabled by the Trace Enable (TRCENA) bit of DEMCR (0xE000EDFC) Debug Exception and monitor control register, which is a global enable bit that enables both the Data Watch Trace (DWT) and Intrumental Trace Module (ITM) on behalf of the debug of the Cortex-M3 microprocessor. The time stamp generator is used during the debug process to set up the break point and marching step, etc.

Figure 3-38 DEMCR Register



Note!

TRCENA is the global enable for DWT and ITM features:

- 0: DWT and ITM units disabled.
- 1: DWT and ITM units enabled.

3.8.7 Timer

GW1NS-2C/GW1NS-4C offers an embedded microprocessor system that contains two synchronous standard timers: Timer0 and Timer1. These can be accessed and controlled through APB1 bus.

Timer0 and Timer1 are 32 bits down-counter with the following features:

- Users can generate an interrupt request signal, TIMERINT, when the counter reaches 0. The interrupt request is held until it is cleared by writing to the INTCLEAR Register.
- Users can employ the zero-to-one transition of the external input signal, EXTIN, as a timer enable.
- If the timer count reaches 0 and, at the same time, the software clears a previous interrupt status, the interrupt status is set to 1.
- The external clock, EXTIN, must be slower than half of the peripheral clock because it is sampled by a double flip-flop before going through edge-detection logic when the external inputs act as a clock.
- Timer0: EXTIN is hard-wired to GPIO[1]
- Timer1: EXTIN is hard-wired to GPIO[6]

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PCLK Synchronizer Reload value Edge detection PCLKG CTRL[2] PRESETn EXTIN 32bits down counter PADDR[11:2] CTRL[1] PENABLE CTRL[0] PWRITE PWDATA[31:0] TIMERINT PSLVERR CTRL[3] CLR PRDATA[31:0] ECOREVNUM[3:0]

Figure 3-39 Timer0/Timer1 Structure View

The Timer0/Timer1 register is as shown in Table 3-18. The Timer0 base address is 0x40000000, and the Timer1 base address is 0x40001000.

Table 3-18 Timer0/Timer1 Register

Name	Base Offset	Туре	Data Width	Reset Value	Description
CTRL	0x000	Read/Write	4	0x0	 [3]: System timer interrupt enable [2]: Select external input as clock [1]: Select external input as enable [0]: Enable
VALUE	0x004	Read/Write	32	0x00000000	Current value
RELOAD	0x008	Read/Write	32	0x00000000	Reload value. Write to this register to set the current value.
INTSTATUS/ INTCLEAR	0x00C	Read/Write	1	0x0	[0]: Timer interrupt. Write one to clear.
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x22	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

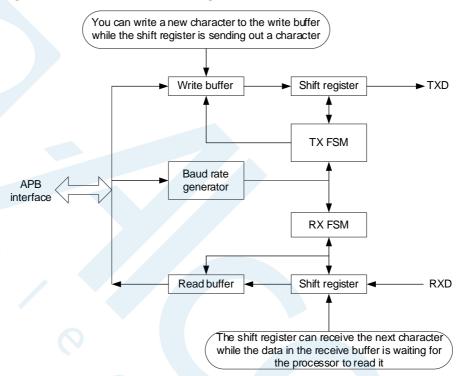
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3.8.8 **UART**

The GW1NS-2C/4C embedded microprocessor system contains two UART: UART0 and UART1. These can be accessed and controlled through APB1 bus, it supports Max. baud rate of 921.6Kbits/s.

UART0 and UART1 support 8 bits communication without parity and one stop bit.

Figure 3-40 APB UART Buffering



UART0 and UART support a high-speed test mode. When CTRL[6] is set to 1, the serial data is transmitted at one bit per clock cycle. This enables you to send text messages in a much shorter simulation time. The APB interface always sends an "OK" response with no wait state. You must program the baud rate divider register BAUDDIV before enabling the UART.

The BAUDTICK output pulses at a frequency of 16 times that of the programmed baud rate. You can use this external signal for capturing UART data in a synchronous environment. The TXEN output signal indicates the status of CTRL[0]. You can use this signal to switch a bidirectional I/O pin in a silicon device to UART data output mode automatically when the UART transmission feature is enabled.

The buffer overrun status in the STATE field is used to drive the overrun interrupt signals. Therefore, clearing the buffer overrun status de-asserts the overrun interrupt, and clearing the overrun interrupt bit also clears the buffer overrun status bit in the STATE field.

See Table 3-19 for the UART Register Description. The UART0 base address is 0x40004000, and the UART1 base address is 0x40005000.

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Table 3-19 UART0/UART1 Register

Name	Base Offset	Туре	Data Width	Reset Value	Description
DATA	0x000	Read/Write	8	0x	8 bits data Read: Received data. Write: Transmit data.
STATE	0x004	Read/Write	4	0x0	[3]: RX buffer overrun, write 1 to clear.[2]: TX buffer overrun, write 1 to clear.[1]: RX buffer full, read-only.[0]: TX buffer full, read-only.
CTRL	0x008	Read/Write	7	0x00	 [6]: High-speed test mode for TX only. [5]: RX overrun interrupt enable. [4]: TX overrun interrupt enable. [3]: RX interrupt enable. [2]: TX interrupt enable. [1]: RX enable. [0]: TX enable.
INTSTATUS/ INTCLEAR	0x00C	Read/Write	4	0x0	[3]: RX overrun interrupt, write 1 to clear.[2]: TX overrun interrupt, write 1 to clear.[1]: RX interrupt, write 1 to clear.[0]: TX interrupt, write 1 to clear.
BAUDDIV	0x010	Read/Write	20	0x00000	[19:0]: Baud rate divider. The minimum number is 16.
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x21	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

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3.8.9 Watchdog

The GW1NS-2C/4C embedded microprocessor system contains one watchdog module. This can be accessed and controlled through the APB1 bus.

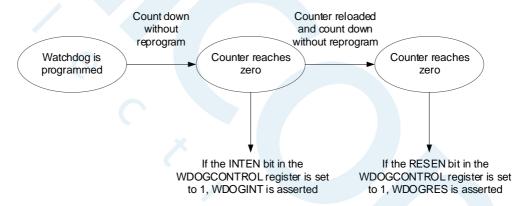
The APB watchdog module is based on a 32 bits down-counter that is initialized from the reload register, WDOGLOAD.

The watchdog module generates a regular interrupt, WDOGINT, depending on a programmed value. The counter decrements by one on each positive clock edge of WDOGCLK when the clock enable, WDOGCLKEN, is HIGH. The watchdog monitors the interrupt and asserts a reset request WDOGRES signal when the counter reaches 0, and the counter is stopped. On the next enabled WDOGCLK clock edge, the counter is reloaded from the WDOGLOAD register and the countdown sequence continues.

The watchdog module applies a reset to a system in the event of a software failure, providing a way to recover from software crashes. For example, if the interrupt is not cleared by the time the counter next reaches 0, the watchdog module initiates the reset signal.

Figure 3-39 below depicts the watchdog operation.

Figure 3-41 Watchdog Operation



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The watchdog register is as shown in Table 3-20. The watchdog base address is 0x40008000.

Table 3-20 Watchdog Register

Name	Base Offset	Туре	Data Width	Reset Value	Description
WDOGLOAD	0x00	Read/ Write	32	0xFFFFFFF	Watchdog Load Register
WDOGVALUE	0x04	Read only	32	0xFFFFFFF	Watchdog Value Register
WDOGCONTROL	0x08	Read/ Write	2	0x0	Watchdog Control Register [1]: [0]:
WDOGINTCLR	0x0C	Write only	-	0x-	Watchdog Clear Interrupt Register
WDOGRIS	0x10	Read only	1	0x0	Watchdog Raw Interrupt Status Register
WDOGMIS	0x14	Read only	1	0x0	Watchdog Interrupt Status Register
WDOGLOCK	0xC00	Read/ Write	32	0x0	Watchdog Lock Register
WDOGTCR	0xF00	Read/ Write	1	0x0	Watchdog Integration Test Control Register
WDOGTOP	0xF04	Write only	2	0x0	Watchdog Integration Test Output Set Register
WDOGPERIPHID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
WDOGPERIPHID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
WDOGPERIPHID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
WDOGPERIPHID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
WDOGPERIPHID0	0XFE0	Read only	8	0x24	Peripheral ID Register 0
WDOGPERIPHID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
WDOGPERIPHID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
WDOGPERIPHID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
WDOGPCELLID0	0XFF0	Read only	8	0X0D	Component ID Register 0
WDOGPCELLID1	0XFF4	Read only	8	0XF0	Component ID Register 1
WDOGPCELLID2	0XFF8	Read only	8	0X05	Component ID Register 2
WDOGPCELLID3	0XFFC	Read only	8	0XB1	Component ID Register 3

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3.8.10 GPIO

The GW1NS-2C/4C microprocessor system communicates with the GPIO block through the AHB bus. The GIPO block interconnects with the FPGA. GPIO provides a 16 bits I/O interface with the following properties:

- Programmable interrupt generation capability. You can configure each bit of the I/O pins to generate interrupts;
- Bit masking support using address values;
- Registers for alternate function switching with pin multiplexing support;
- Thread safe operation by providing separate set and clear addresses for control registers.

The GPIO register is as shown in Table 3-21. The GPIO base address is 0 x 40010000.

Table 3-21 GPIO Register

Name	Base Offset	Туре	Data Width	Reset Value	Description
DATA	0x0000	Read/Write	16	0x	Data value [15:0]
DATAOUT	0x0004	Read/Write	16	0x0000	Data output register value [15:0]
OUTENSET	0x0010	Read/Write	16	0x0000	Output enable set [15:0] Write 1: Set the output enable bit. Write 0: No effect. Read 1: Indicates the signal direction as output. Read 0: Indicates the signal direction as input.
OUTENCLR	0x0014	Read/Write	16	0x0000	Output enable clear [15:0]
ALTFUNCSET	0x0018	Read/Write	16	0x0000	Alternative function set [15:0] Write 1: Sets the ALTFUNC bit. Write 0: No effect. Read 0: GPIO as I/O Read 1: ALTFUNC Function
ALTFUNCCLR	0x001C	Read/Write	16	0x0000	Alternative function clear [15:0]
INTENSET	0x0020	Read/Write	16	0x0000	Interrupt enable set [15:0] Write 1: Sets the enable bit. Write 0: No effect. Read 0: Interrupt disabled. Read 1: Interrupt enabled.
INTENCLR	0x0024	Read/Write	16	0x0000	Interrupt enable clear [15:0] Write 1: Clear the enable bit. Write 0: No effect. Read 0: Interrupt disabled. Read 1: Interrupt enabled.
INTTYPESET	0x0028	Read/Write	16	0x0000	Interrupt type set [15:0]
INTTYPECLR	0x002C	Read/Write	16	0x0000	Interrupt type clear [15:0]
INTPOLSET	0x0030	Read/Write	16	0x0000	Polarity-level, edge interrupt request configuration [15:0]

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Name	Base Offset	Туре	Data Width	Reset Value	Description
INTPOLCLR	0x0034	Read/Write	16	0x0000	Polarity-level, edge interrupt request configuration [15:0]
INTSTATUS/ INTCLEAR	0x0038	Read/Write	16	0x0000	Read interrupt status register Write 1: Clear the interrupt request
MASKLOWBYT E	0x0400- 0x07FC	Read/Write	16	0x0000	_
MASKHIGHBY TE	0x0800- 0x0BFC	Read/Write	16	0x0000	_
Reserved	0x0C00- 0x0FCF	_	_	_	Reserved
PID4	0XFD0	Read only	8	0x04	Peripheral ID Register 4
PID5	0XFD4	Read only	8	0x00	Peripheral ID Register 5
PID6	0XFD8	Read only	8	0x00	Peripheral ID Register 6
PID7	0XFDC	Read only	8	0x00	Peripheral ID Register 7
PID0	0XFE0	Read only	8	0x20	Peripheral ID Register 0
PID1	0XFE4	Read only	8	0XB8	Peripheral ID Register 1
PID2	0XFE8	Read only	8	0X1B	Peripheral ID Register 2
PID3	0XFEC	Read only	8	0X00	Peripheral ID Register 3
CID0	0XFF0	Read only	8	0X0D	Component ID Register 0
CID1	0XFF4	Read only	8	0XF0	Component ID Register 1
CID2	0XFF8	Read only	8	0X05	Component ID Register 2
CID3	0XFFC	Read only	8	0XB1	Component ID Register 3

3.8.11 Debug Access Port

The Cortex-M3 processor block contains a DAP that consist of a JTAG DAP and a TPIU port. Both interface to the FPGA Fabric. The JTAG-DAP is based on the IEEE1149.1 Joint Test Action Group Boundary-Scan Standard.

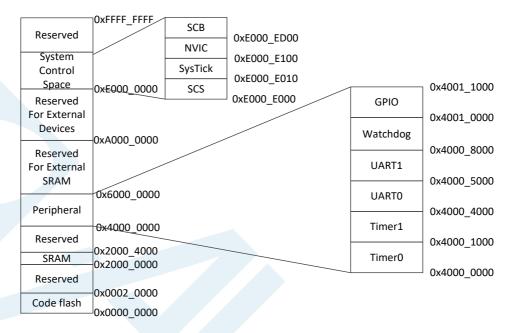
JTAG-DP functions consist of the following three parts:

- JTAG-DP sate machine
- Instruction register (IR) and the related IR scan chain, which are used to control JTAG and the current register actions
- DR register and the related DR scan chain, which connect with the JTAG-DP register.

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3.8.12 Memory Mapping

Figure 3-42 Memory Mapping



3.8.13 Application

The Cortex-M3 IP can be called in Gowin YunYuan software. For further information, please refer to IPUG517, *GW1NS-2C MCU Hardware Design Reference Manual.*

3.9 USB2.0 PHY

3.9.1 Features

GW1NS-2C/2 offers USB2.0 PHY, with the features as below:

- 480Mbps data speed, compatible with USB1.1 1.5/12Mbps data speed
- Plug and play
- Hot socket

3.9.2 Interfaces and Ports Signal

The USB2.0 PHY module includes UTMI+digital and UTMI+AFE (Analog Front End), which are mainly used to connect the USB controller and USB PHY.

Table 3-22 USB2.0 PHY Ports Signal

Port Name	I/O	Description
CLK	0	Used for receiving and sending clock signals Data bit width is 8bit: 60MHz Data bit width is 16bit: 30MHz
RESET	1	Reset signal, active-high.
XCVRSEL	ı	Transceiver select. This signal selects between the LS, FS, and HS transceivers: 2'b00: HS Transceiver

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2501: FS Transceiver 2501: LS Transceiver 2500: LS Transceiver 2501: LS Transceiver 2500: LS Transceiver	Port Name	I/O	Description
TERMSEL I Termination select. This signal selects between the FS and HS terminations: 0: HS termination enabled 1: FS termination enabled Line state. These signals reflect the current state of the single ended receivers. 2'b00: SE0 2'b01: 'J' state 2'b10: 'K' state 2'b11: SE1 CLKSEL [1:0] I 2'b01: Non-driving 2'b11: Normal operation 2'b11: Normal operation 2'b11: Normal operation without automatic generation of start and end signals DP IO USB data pin DM IO USB data pin DATAIN[7:0] I Lower 8 bits USB sends data input TXVLD I Lower 8 bits sends data enable signal, DATAIN[7:0] data valid indication TXVLDH I Higher 8 bits uSB receives data output DATAOUT[7:0] O Lower 8 bits USB receives data output RXVLD O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Higher 8 bits uSB receives data output RXVLDH O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Higher 8 bits receives data enable signal, DATAIN[7:0] data valid indication RXVLDH O Receive active. Indicates that the receive state machine has detected SYNC and is active. RXERROR O Receive Error. High-level indicates that a receive error has been detected. IDPULLUP I Signal that enables the sampling of the analog Id line, active-high.			
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RXACTIVE O Receive active. Indicates that the receive state machine has detected SYNC and is active. RXERROR O Receive Error. High-level indicates that a receive error has been detected. IDPULLUP I Signal that enables the sampling of the analog Id line, active-high. Indicates whether the connected plug is a mini-A or mini-B. O: mini-A	RXVLD	0	
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Indicates whether the connected plug is a mini-A or mini-B. O: mini-A	RXERROR	0	
IDDIG O 0: mini-A	IDPULLUP	I	Signal that enables the sampling of the analog Id line, active-high.
IDDIG O 0: mini-A			Indicates whether the connected plug is a mini-A or mini-B.
1. mini-R	IDDIG	0	
			1: mini-B

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Port Name	I/O	Description
25221// 5		Indicates if the session for an A/B-peripheral is valid.
SESSVLD	0	0: Vbus < 0.8V
		1: Vbus > 2V
		Indicates if the voltage on Vbus is at a valid level for operation (4.4V < Vth < 4.75V).
VBUSVLD	0	0: Vbus < 4.4V
		1: Vbus > 4.75V
		Indicates the voltage on Vbus.
ADPSNS	0	0: Vbus < 0.2 V
7101 0140		1: Vbus > 0.55V
		Enables/disables the ADP Probe comparator.
ADP_PRBEN	1	1: enable
ADI _I KDLN	1	0: disable
ADPPRB	0	Indicates the voltage on Vbus. 0: Vbus < 0.6V
AUPPRB	U	1: Vbus > 0.75V
CHARGVBUS	ı	This signal enables charging Vbus. 0: do not charge Vbus through a resistor
CHARGVBUS	I	charge Vous through a resistor charge Vbus through a resistor
<u> </u>		
DISCHARGEVB	ı	This signal enables charging Vbus. 0: do not discharge Vbus through a resistor
US		do not discharge vous through a resistor discharge Vous through a resistor
		This signal enables the 15k Ohm pull-down resistor on the DP line.
DPPD	1 0	0: Pull-down resistor not connected to DP
5115		1: Pull-down resistor connected to DP
		This signal enables the 15k Ohm pull-down resistor on the DM line.
DMPD	1	0: Pull-down resistor not connected to DM
		1: Pull-down resistor connected to DM
		This signal is used for all types of peripherals connected to it. It is
HOSTDIS	0	only valid when DPPD and DMPD are 1.
11001210		0: there is peripherals connected
		1: there is no peripheral connected
		Indicates if the data on the DataOut[7:0] lines needs to be bitstuffed or not.
TXBITSTUFFEN	1	0: Bitstuffing is disabled
		1: Bitstuffing is enabled
		Indicates if the data on the DataOut[15:8] lines needs to be bitstuffed
TXBITSTUFFEN H		or not.
	I	0: Bitstuffing is disabled
		1: Bitstuffing is enabled
FSLSSERIAL	1	0: FS and LS packets are sent using the parallel interface.
· OLOGEINIAE	•	1: FS and LS packets are sent using the serial interface.
TXENN	I	Active low enable signal. Only used when FSLSSERIAL is set to 1b.
TXDAT	1	Serial data. Only used when FSLSSERIAL is set to 1.

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Port Name	I/O	Description	
TXSE0	I	Force single-ended zero. Only used when FSLSSERIAL is set to 1.	
RXDP	О	Single-ended receive data. This signal is only valid when FSLSSERIAL is set to 1.	
RXDM	0	Single-ended receive data. This signal is only valid when FSLSSERIAL is set to 1.	
RXRCV	0	Single-ended receive data. This signal is only valid when FSLSSERIAL is set to 1.	
VBUS	Ю	VBUS signal	
ID	1	ID signal	
XIN	1	Crystal in signals, supported range is 12MHZ~24MHZ.	
XOUT	0	Crystal out signals	
REXT	I	1% precision 12.7K pull-down register	
LBKERR	0	0: no BIST error 1: Error during BIST occurs	
INTCLK	I	Clock signals provided internally of the SoC.	
CLKRDY	0	Observation/debug signal to show that the internal PLL has locked and is ready.	
CLK480PAD	0	480 MHZ clock output for observation	
Scan signals	ı		
SCANCLK	1	Clock signals for scan mode	
SCANEN	1	Select to shift mode	
SCANMODE	I	High effective signal to enter scan mode	
TRESETN	1	Low effective reset signal for scan mode.	
SCANIN1	I	Scan chain input	
SCANIN2	1	Scan chain input	
SCANIN3	I	Scan chain input	
SCANIN4	1	Scan chain input	
SCANIN5	1	Scan chain input	
SCANIN6	1	Scan chain input	
SCANOUT1	О	Scan chain output	
SCANOUT2	0	Scan chain output	
SCANOUT3	0	Scan chain output	
SCANOUT4	0	Scan chain output	
SCANOUT5	О	Scan chain output	
SCANOUT6	0	Scan chain output	

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Table 3-23 USB2.0 PHY Parameters

Name	Description
	Selects between 8 bits and 16 bits data transfers.
DATABUS16_8	1: 16 bits data path operation enabled. CLK is 30MHz.
	0: 8 bits data path operation enabled. CLK is 60MHz.
ADP_PRBEN	Enables/disables the ADP probe comparator.
TEST_MODE[0]	Enables/disables BIST test
	BIST modes selection
TECT MODEIAL	2'b00: high speed BIST mode
TEST_MODE[4] TEST_MODE[1]	2'b01: full speed BIST mode
TEGT_WODE[1]	2'b10: low speed BIST mode
	2'b11: Low speed packet on FSBUS BIST
TEST_MODE[2]	0: 8 bits interface BIST
TEST_WODE[2]	1: 16 bits interface BIST
TEST_MODE[3]	0: digital loop back BIST
TEOT_MODE[o]	1: analog loop back BIST
HSDRV1	High speed drive adjustment. Please connect to 0 for normal operation.
HSDRV0	High speed drive adjustment. Please connect to 0 for normal operation.
	Source select for clock
CLK_SEL	0: external crystal oscillator XIN/XOUT
	1: SoC internal clock INTCLK
	Used for test, M division factor, default value 0
	0: 1 frequency division
	1: disabled
M[3: 0]	2: 2 frequency division
	3: 3 frequency division
	15: 15 frequency division
	Used for test, N division factor, default value 0
	Supports 2 - 63
NIE O	0 and 1: disabled
N[5: 0]	2: 2 frequency division 3: 3 frequency division
	3: 3 frequency division
	63: 63 frequency division
	Used for test, charge pump current control signal, default 40uA
	2'b00: 30uA
C[1: 0]	2'b01: 40uA
5[0]	2'b10: 50uA
	2'b11: 60uA
	Used for test, default 0
FOC_LOCK	0: LOCK is generated by PLL lock detector
	1: LOCK is always high(always lock)

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3 Architecture 3.10 ADC

3.10 ADC

3.10.1 Features

GW1NS-2C/2 integrates an eight-channel single-ended 12 bits SAR ADC. It is a medium-speed ADC with low-power, low-leakage current, and high-speed.

The dynamic performance is as below:

- Slew Rate: Max. 1MHz
- Dynamic range: >81 dB SFDR, >62 db SINAD
- Linear performance: INL<1 LSB, DNL<0.5 LSB, no missing codes

The reference voltage of ADC is as below:

- Reference voltages can be enabled/disabled by configuration parameters.
 - VREF_EN=1, enabling.
 - VREF_EN=0, not enabled, at which point Vref is provided by Vccx.
- When Vref is enabled, there are two ways to provide Vref: internally and externally.
 - Internal is provided by Vccx, which supports 7 reference voltages by configuring the parameter VREF_SEL.
 - External is provided by the IO pin VREF.

3.10.2 Port Signal

Table 3-24 ADC Port Signal

Port Name	I/O	Description
CLK		Clock input signal. fclk is greater than or equal to 16 times of sampling frequency Max. Clock frequency: 16MHz
PD	1	Power down signal, output 0 when the signal value is 1.
SoC	1	Sampling frequency, max. Frequency is 1MHz.
S[2: 0]	1	Channel selection signal
CH[7:0]	I	Eight-channel analog input
EOC	0	End conversion.
B[11: 0]	0	A/D conversion result

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3 Architecture 3.11 Clock

Table 3-25 Channel Selection Truth Table

S[2: 0]	Selected Input Channel
3'b111	CH[7]
3'b110	CH[6]
3'b101	CH[5]
3'b100	CH[4]
3'b011	CH[3]
3'b010	CH[2]
3'b001	CH[1]
3'b000	CH[0]

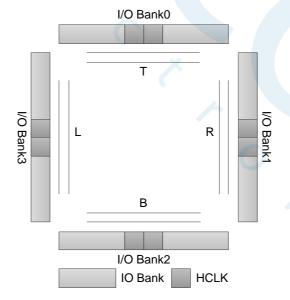
3.11 Clock

The clock resources and wiring are critical for high-performance applications in FPGA. The GW1NS series of FPGA products provide the global clock network (GCLK), which connects to all the registers directly. Besides the global clock network, the GW1NS series of FPGA products provide high-speed clock HCLK. PLL, etc are also provided.

3.11.1 Global Clock

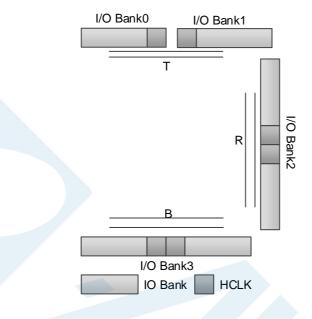
The GCLK is distributed in the GW1NS series of FPGA products as two quadrants: L and R. Each quadrant provides eight GCLKs. The optional clock resources of GCLK can be pins or CRU. Users can employ dedicated pins as clock resources to achieve better timing.

Figure 3-43 GW1NS-2C/2 Clock Resources



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Figure 3-44 GW1NS-4C/4 Clock Resources



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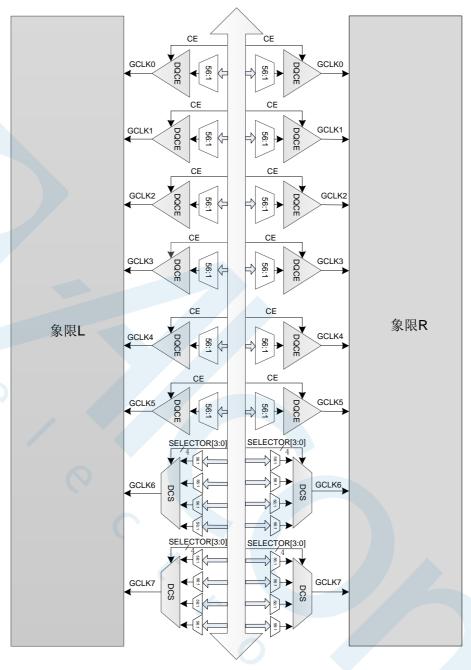
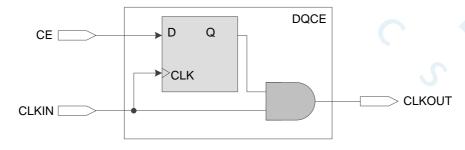


Figure 3-45 GCLK Quadrant Distribution

GCLK0~GCLK5 can be turned on or off by Dynamic Quadrant Clock Enable (DQCE). When GCLK0~GCLK5 in the quadrant is off, all the logic driven by it will not toggle; therefore, lower power can be achieved.

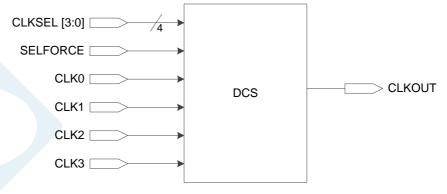
Figure 3-46 DQCE Concept



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GCLK6~GCLK7 of each quadrant is controlled by the DCS, as shown in Figure 3-47. Select dynamically between CLK0~CLK3 by CRU, and output a glitch-free clock.

Figure 3-47 DCS Concept

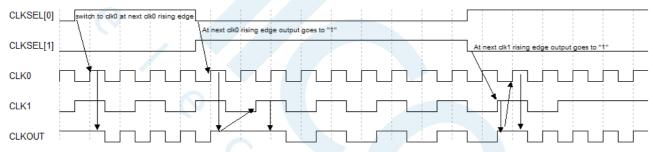


DCS can be configured in the following modes:

DCS Rising Edge

Stay as 1 after current selected clock rising edge, and the new select clock will be effective after its first rising edge, as shown in Figure 3-48.

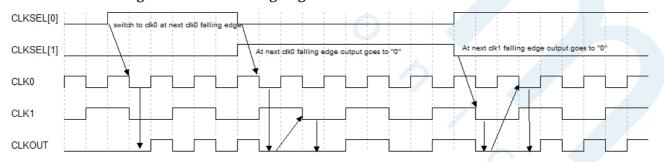
Figure 3-48 DCS Rising Edge



DCS Falling Edge

Stay as 0 after current selected clock falling edge, and the new select clock will be effective after its first falling edge, as shown in Figure 3-49.

Figure 3-49 DCS Falling Edge



3. Clock Buffer Mode

In this mode, DCS acts as a clock buffer.

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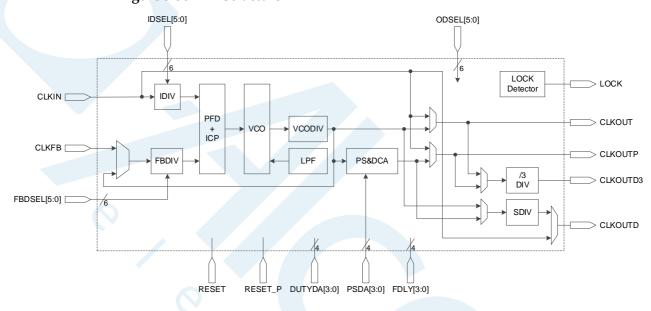
3.11.2 PLL

Phase-locked Loop (PLL) is one kind of a feedback control circuit. The frequency and phase of the internal oscillator signal is controlled by the external input reference clock.

PLL blocks provide the ability to synthesize clock frequencies. Frequency adjustment (multiply and division), phase adjustment, and duty cycle can be adjusted by configuring the parameters.

See Figure 3-50 for the PLL structure.

Figure 3-50 PLL Structure



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See Table 3-26 for a definition of the PLL ports.

Table 3-26 Definition of the PLL Ports

Port Name	Signal	Description
CLKIN [5:0]	Ι	Reference clock input
CLKFB	Ι	Feedback clock input
RESET	Ι	PLL reset
RESET_P	Ι	PLL Power Down
IDSEL [5:0]	Ι	Dynamic IDIV control: 1~64
FBDSEL [5:0]	Ι	Dynamic FBDIV control:1~64
PSDA [3:0]	Ι	Dynamic phase control (rising edge effective)
DUTYDA [3:0]	1	Dynamic duty cycle control (falling edge effective)
FDLY[3:0]		CLKOUTP dynamic delay control
CLKOUT	0	Clock output with no phase and duty cycle adjustment
CLKOUTP	0	Clock output with phase and duty cycle adjustment
CLKOUTD	0	Clock divider from CLKOUT and CLKOUTP (controlled by SDIV)
CLKOUTD3	0	clock divider from CLKOUT and CLKOUTP (controlled by DIV3 with the constant division value 3)
		PLL lock status:
LOCK	0	1: locked,
		0: unlocked

The PLL reference clock source can come from an external PLL pin or from internal routing GCLK, HCLK, or general data signal. PLL feedback signal can come from the external PLL feedback input or from internal routing GCLK, HCLK, or general data signal.

For the PLL features, please refer to Table 4-20 PLL Parameters.

PLL can adjust the frequency of the input clock CLKIN (multiply and division). The formulas for doing so are as follows:

- 1. $f_{CLKOUT} = (f_{CLKIN}*FBDIV)/IDIV$
- 2. $f_{VCO} = f_{CLKOUT}*ODIV$
- 3. $f_{CLKOUTD} = f_{CLKOUT}/SDIV$
- 4. $f_{PFD} = f_{CLKIN}/IDIV = f_{CLKOUT}/FBDIV$

Note!

- f_{CLKIN}: The frequency of the input clock CLKIN
- f_{CLKOUT}: The clock frequency of CLKOUT and CLKOUTP
- f_{CLKOUTD}: The clock frequency of CLKOUTD, and CLKOUTD is the clock CLKOUT after division
- f_{PFD}: PFD Phase Comparison Frequency, and the minimum value of f_{PFD} should be no less than 3MHz.

Adjust IDIV, FBDIV, ODIV, and SDIV to achieve the required clock

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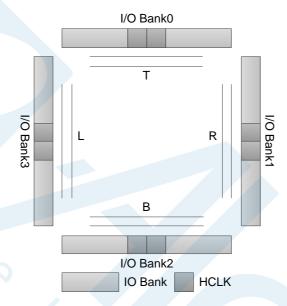
3 Architecture 3.12 Long Wire (LW)

frequency.

3.11.3 HCLK

HCLK is the high-speed clock in the GW1NS series of FPGA products. It can support high-performance data transfer and is mainly suitable for source synchronous data transfer protocols. See Figure Figure 3-51.

Figure 3-51 GW1NS-2 HCLK Distribution



3.12 Long Wire (LW)

As a supplement to CRU, the GW1NS series of FPGA products provide another routing resource, Long Wire, which can be used as clock, clock enable, set/reset, or other high fan out signals.

3.13 Global Set/Reset (GSR)

A global set/rest (GSR) network is built into the GW1NS series of FPGA products. There is a direct connection to core logic. It can be used as asynchronous/synchronous set or asynchronous/synchronous reset. The registers in CFU and I/O can be individually configured to use GSR.

3.14 Programming Configuration

The GW1NS series of FPGA products support SRAM programming and Flash programming. The Flash programming mode supports on-chip Flash and off-chip Flash. GW1NS-2/2C supports on-chip DUAL BOOT. Users can also backup data to external Flash according to requirements.

Besides JTAG, the GW1NS series of FPGA products also supports GOWINSEMI's own configuration mode: GowinCONFIG (AUTO BOOT, SSPI, MSPI, DUAL BOOT, SERIAL, and CPU). All the devices support JTAG and AUTO BOOT. Users can configure the Mode value to select the required programming mode. For more detailed information, please refer to UG290, Gowin FPGA Products Programming and Configuration User Guide.

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3 Architecture 3.15 On Chip Oscillator

3.14.1 SRAM Configuration

When you adopt SRAM to configure the device, every time the device is powered on, the bit stream file needs to be downloaded to configure the devicee.

3.14.2 Flash Configuration

The Flash configuration data is stored in the on-chip flash. Each time the device is powered on, the configuration data is transferred from the Flash to the SRAM, which controls the working of the device. This mode can complete configuration within a few ms, and is referred to as "Quick Start". The GW1NS series of FPGA products also support off-chip Flash configuration and dual-boot. Please refer to UG290, Gowin FPGA Products Programming and Configuration User Guide for more detailed information.

3.15 On Chip Oscillator

There is an internal oscillator in each of the GW1NS-2 series of FPGA products. This provides a programmable user clock that offers clock precision of ±5%. During the configuration process, it can provide a clock for the MSPI mode.

The internal oscillator of GW1NS-4C/4 supports user-configurable power saving mode.

The on-chip oscillator also provides a clock resource for user designs. Up to 64 clock frequencies can be obtained by setting the parameters.

The following formula is employed to get the GW1NS-2/2C output clock frequency: fout=240 MHz/Param.

The following formula is employed to get the GW1NS-4/4C output clock frequency: fout=240 MHz/Param.

Note!

"Param" is the configuration parameter with a range of 2~128. It supports even number only.

Table 3-27 and Table 3-28 list some Oscillator output frequency options.

Table 3-27 Oscillator Output Frequency Options for GW1NS-2C/2

Mode ³	Frequency	Mode	Frequency	Mode	Frequency
0	2.5MHz ¹	8	7.5MHz	16	15.0MHz
1	5.2MHz	9	8.0MHz	17	17.1MHz
2	5.4MHz	10	8.6MHz	18	20.0MHz
3	5.7MHz	11	9.2MHz	19	24.0MHz
4	6.0MHz	12	10.0MHz	20	30.0MHz
5	6.3MHz	13	10.9MHz	21	40.0MHz
6	6.6MHz	14	12.0MHz	22	60.0MHz
7	7.0MHz	15	13.3MHz	23	120MHz ²

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3 Architecture 3.15 On Chip Oscillator

Table 3-28 Oscillator Output Frequency Options for GW1NS-4C/4

Mode ³	Frequency	Mode	Frequency	Mode	Frequency
0	2.5MHz ¹	8	7.8MHz	16	15.6MHz
1	5.4MHz	9	8.3MHz	17	17.9MHz
2	5.7MHz	10	8.9MHz	18	21MHz
3	6.0MHz	11	9.6MHz	19	25MHz
4	6.3MHz	12	10.4MHz	20	31.3MHz
5	6.6MHz	13	11.4MHz	21	41.7MHz
6	6.9MHz	14	12.5MHz	22	62.5MHz
7	7.4MHz	15	13.9MHz	23	125MHz ²

Note!

- [1] Default frequency
- [2] 125MHz is not suitable for MSPI. "Mode" here is just a label instead of "Param".

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4 AC/DC Characteristic

Note!

Please ensure that you use GOWINSEMI devices within the recommended operating conditions and range. Data beyond the working conditions and range are for reference only. GOWINSEMI does not guarantee that all devices will operate normally beyond the operating conditions and range.

4.1 Operating Conditions

4.1.1 Absolute Max. Ratings

Table 4-1 Absolute Max. Ratings

Name	Description	Min.	Max.
V _{CC}	Core voltage	-0.5V	1.32V
V _{cco}	I/O Bank Power	-0.5V	3.75V
	LX Auxiliary voltage	-0.5V	1.98V
V _{ccx}	UX Auxiliary voltage	-0.5V	3.75V
	LV Auxiliary voltage	-0.5V	3.75V
Storage Temperature	Storage Temperature	-65 °C	+150 ℃
Junction Temperature	Junction Temperature	-40 °C	+125 ℃

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4.1.2 Recommended Operating Conditions

Table 4-2 Recommended Operating Conditions

Name	Description	Min.	Max.
V _{CC}	Core voltage	1.14V	1.26V
V _{cco}	I/O Bank Power	1.14V	3.465V
	LX I/O Bank voltage	1.14V	1.89V
	UX I/O Bank voltage UX V_{CCX} needs to be greater than ot equals to V_{CCOX}	1.14V	3.465V
V _{CCOx}	LV I/O Bank voltage	1.14V	3.465V
	LX Auxiliary voltage	1.71V	1.89V
	UX Auxiliary voltage UX V_{CCX} needs to be greater than ot equals to V_{CCOx}	2.375V	3.465V
V _{CCX}	LV Auxiliary voltage	1.71V	3.465V
T _{JCOM}	Junction temperature Commercial operation	0 ℃	+85 °C
T _{JIND}	Junction temperature Industrial operation	-40 °C	+100 °C

Note!

For the recommended power requirements of different packages, please refer to <u>UG822, GW1NS-2 Pinout</u>, <u>UG825, GW1NS-2C Pinout</u>, and <u>UG824, GW1NS-4&4C Pinout</u>

4.1.3 Power Supply Ramp Rates

Table 4-3 Power Supply Ramp Rates

Name	Description	Min.	Тур.	Max.
T _{RAMP}	Power supply ramp rates for all power supplies	0.6mV/µs	-	6mV/µs

4.1.4 Hot Socket Specifications

Table 4-4 Hot Socket Specifications

Name	Description	Condition	1/0	Max.
I _{HS}	Input or I/O leakage current	0 <v<sub>IN<v<sub>IH(MAX)</v<sub></v<sub>	I/O	150uA
I _{HS}	Input or I/O leakage current	0 <v<sub>IN<v<sub>IH(MAX)</v<sub></v<sub>	TDI,TDO, TMS,TCK	120uA

4.1.5 POR Specification

Table 4-5 POR Specification

Name	Description	Min.	Max.
POR voltage value	Power on reset voltage of Vcc	TBD	TBD

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4 AC/DC Characteristic 4.2 ESD

4.2 ESD

Table 4-6 GW1NS ESD - HBM

Device	GW1NS-2C	GW1NS-2	GW1NS-4C	GW1NS-4
CS36	HBM>1,000V	HBM>1,000V	_	_
CS36U	-	HBM>1,000V	_	-
QN32	HBM>1,000V	HBM>1,000V	_	-
QN32U	HBM>1,000V	HBM>1,000V	_	_
QN48	HBM>1,000V	HBM>1,000V	HBM>1,000V	HBM>1,000V
LQ144	HBM>1,000V	HBM>1,000V		
CS49	-	-	HBM>1,000V	HBM>1,000V
MG64	-	-	HBM>1,000V	HBM>1,000V

Table 4-7 GW1NS ESD - CDM

Device	GW1NS-2C	GW1NS-2	GW1NS-4C	GW1NS-4
CS36	CDM>500V	CDM>500V	-	_
CS36U	-	CDM>500V	-	-
QN32	CDM>500V	CDM>500V	-	-
QN32U	CDM>500V	CDM>500V	_	_
QN48	CDM>500V	CDM>500V	CDM>500V	CDM>500V
LQ144	CDM>500V	CDM>500V		
CS49	-	-	CDM>500V	CDM>500V
MG64	_	-	CDM>500V	CDM>500V

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4.3 DC Electrical Characteristics

4.3.1 DC Electrical Characteristics over Recommended Operating Conditions

Table 4-8 DC Electrical Characteristics over Recommended Operating Conditions

Name	Description	Condition	Min.	Тур.	Max.
	Input or I/O leakage	V _{CCO} <v<sub>IN<v<sub>IH (MAX)</v<sub></v<sub>	-	-	210µA
I_{IL},I_{IH}	input of I/O leakage	0V <v<sub>IN<v<sub>CCO</v<sub></v<sub>	-	-	10µA
I _{PU}	I/O Active Pull-up Current	0 <v<sub>IN<0.7V_{CCO}</v<sub>	-30 µA	-	-150 µA
I _{PD}	I/O Active Pull-down Current	V _{IL} (MAX) <v<sub>IN<v<sub>CCO</v<sub></v<sub>	30μΑ	-	150µA
I _{BHLS}	Bus Hold Low Sustaining Current	V _{IN} =V _{IL} (MAX)	30μΑ	-	-
I _{BHHO}	Bus Hold High Sustaining Current	V _{IN} =0.7V _{CCO}	-30 μΑ	-	-
I _{BHLO}	Bud HoldLow Overdrive Current	0≤V _{IN} ≤V _{CCO}	-	-	150µA
I _{BHHO}	BusHoldHigh Overdrive Current	0≤V _{IN} ≤V _{CCO}	-	-	-150 μA
V_{BHT}	Bus hold trip points		V _{IL} (MAX)	-	V _{IH} (MIN)
C1	I/O Capacitance			5pF	8pF
		V _{CCO} =3.3V, Hysteresis= Large	-	482mV	-
	0	V _{CCO} =2.5V, Hysteresis= Large	-	302mV	-
		V _{CCO} =1.8V, Hysteresis= Large	-	152mV	-
V _{HYST}	Hysteresis for Schmitt Trigge	V _{CCO} =1.5V, Hysteresis= Large	-	94mV	-
VHYST	inputs	V _{CCO} =3.3V, Hysteresis= Small		240mV	-
		V _{CCO} =2.5V, Hysteresis= Small	-	150mV	-
		V _{CCO} =1.8V, Hysteresis= Small	-	75mV	-
		V _{CCO} =1.5V, Hysteresis= Small	-	47mV	-

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4.3.2 Static Supply Current

Table 4-9 Static Supply Current

Name	Description	LV/UV	Device	Min.	Тур.	Max.
Icc	Core current V _{CCX} =3.3V,	UX	GW1NS-2	TBD	TBD	TBD
	V _{CCX} current	UX	GW1NS-2	TBD	TBD	TBD
I _{CCX}	V _{CCX} current	UX	GW1NS-2	TBD	TBD	TBD
Icco	I/O Bank current	UX	GW1NS-2	TBD	TBD	TBD
Icc	Core current under load	UX	GW1NS-2	TBD	TBD	TBD
I _{ccx}	Core current under load	UX	GW1NS-2	TBD	TBD	TBD
I _{cco}	I/O Bank current under load	UX	GW1NS-2	TBD	TBD	TBD
Icc	Core current under load	LV	GW1NS-4	TBD	TBD	TBD
I _{ccx}	V _{CCX} current under load	LV	GW1NS-4	TBD	TBD	TBD
I _{cco}	I/O Bank current under load	LV	GW1NS-4	TBD	TBD	TBD

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4.3.3 Recommended I/O Operating Conditions

Table 4-10 Recommended I/O Operating Conditions

Name	Output V _C	co (V)		Input V _{REF}	(V)	
Name	Min.	Тур.	Max.	Min.	Тур.	Max.
LVTTL33	3.135	3.3	3.465	-	-	-
LVCMOS33	3.135	3.3	3.465	-	-	-
LVCMOS25	2.375	2.5	2.625	-	-	-
LVCMOS18	1.71	1.8	1.89	-	-	-
LVCMOS15	1.425	1.5	1.575	-	-	-
LVCMOS12	1.14	1.2	1.26	-	-	-
SSTL15	1.425	1.5	1.575	0.68	0.75	0.9
SSTL18_I	1.71	1.8	1.89	0.833	0.9	0.969
SSTL18_II	1.71	1.8	1.89	0.833	0.9	0.969
SSTL25_I	2.375	2.5	2.645	1.15	1.25	1.35
SSTL25_II	2.375	2.5	2.645	1.15	1.25	1.35
SSTL33_I	3.135	3.3	3.465	1.3	1.5	1.7
SSTL33_II	3.135	3.3	3.465	1.3	1.5	1.7
HSTL18_I	1.71	1.8	1.89	0.816	0.9	1.08
HSTL18_II	1.71	1.8	1.89	0.816	0.9	1.08
HSTL15	1.425	1.5	1.575	0.68	0.75	0.9
PCl33	3.135	3.3	3.465	-	-	-
LVPECL33E	3.135	3.3	3.465	-	-	-
MLVDS25E	2.375	2.5	2.625	-	-	-
BLVDS25E	2.375	2.5	2.625	-	-	-
RSDS25E	2.375	2.5	2.625	-	-	-
LVDS25E	2.375	2.5	2.625	-	-	-
SSTL15D	1.425	1.5	1.575	-	-	-
SSTL18D_I	1.71	1.8	1.89	-	-	-
SSTL18D_II	1.71	1.8	1.89	-	-	-
SSTL25D_I	2.375	2.5	2.625	-	-	-
SSTL25D_II	2.375	2.5	2.625	-	-	-
SSTL33D_I	3.135	3.3	3.465	-	-	-
SSTL33D_II	3.135	3.3	3.465	-	-	-
HSTL15D	1.425	1.575	1.89	-	-	-
HSTL18D_I	1.71	1.8	1.89	-	-	-
HSTL18D_II	1.71	1.8	1.89	-		-

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4.3.4 IOB Single - Ended DC Electrical Characteristic

Table 4-11 IOB Single - Ended DC Electrical Characteristic

Nama	V _{IL}		V _{IH}		V _{OL}	V _{OH}	I _{OL}	I _{OH}
Name	Min	Max	Min	Max	(Max)	(Min)	(mA)	(mA)
							4	-4
							8	-8
LVCMOS33	-0.3V	0.8V	2.0V	3.6V	0.4V	V_{CCO} -0.4 V	12	-12
LVTTL33	-0.3 V	0.6 V	2.U V	3.0 V			16	-16
							24	-24
					0.2V	V _{CCO} -0.2V	0.1	-0.1
							4	-4
					0.4V	V _{CCO} -0.4V	8	-8
LVCMOS25	-0.3V	0.7V	1.7V	3.6V	U.4 V	V _{CCO} -0.4 V	12	-12
							16	-16
					0.2V	V _{CCO} -0.2V	0.1	-0.1
							4	-4
					0.4V	$V_{CCO}0.4V$	8	-8
LVCMOS18	-0.3V	0.35 x V _{CCO}	$0.65 \times V_{CCO}$	3.6V			12	-12
					0.2V	V _{CCO} -0.2V	0.1	-0.1
					0.41/	V _{CCO} -0.4V	4	-4
LVCMOS15	-0.3V	0.35 x V _{CCO}	0.65 x V _{CCO}	3.6V	0.4V		8	-8
					0.2V	V _{CCO} -0.2V	0.1	-0.1
					0.4V	V04V	2	-2
LVCMOS12	-0.3V	0.35 x V _{CCO}	0.65 x V _{CCO}	3.6V	0.4 V	V _{CCO} -0.4V	6	-6
		•			0.2V	V _{CCO} -0.2V	0.1	-0.1
PCI33	-0.3V	0.3 x V _{CCO}	0.5 x V _{CCO}	3.6V	0.1 x V _{CCO}	0.9 x V _{CCO}	1.5	-0.5
SSTL33_I	-0.3V	V _{REF} -0.2V	V _{REF} +0.2V	3.6V	0.7	V _{CCO} -1.1V	8	-8
SSTL25_I	-0.3V	V _{REF} -0.18V	V _{REF} +0.18V	3.6V	0.54V	V _{CCO} -0.62V	8	-8
SSTL25_II	-0.3V	V _{REF} -0.18V	V_{REF} +0.18 V	3.6V	NA	NA	NA	NA
SSTL18_II	-0.3V	V _{REF} -0.125V	V _{REF} +0.125V	3.6V	NA	NA	NA	NA
SSTL18_I	-0.3V	V _{REF} -0.125V	V _{REF} +0.125V	3.6V	0.40V	V _{CCO} -0.40V	8	-8
SSTL15	-0.3V	V _{REF} -0.1V	V _{REF} + 0.1V	3.6V	0.40V	V _{CCO} -0.40V	8	-8
HSTL18_I	-0.3V	V _{REF} -0.1V	V _{REF} + 0.1V	3.6V	0.40V	V _{CCO} -0.40V	8	-8
HSTL18_II	-0.3V	V _{REF} -0.1V	V _{REF} + 0.1V	3.6V	NA	NA	NA	NA
HSTL15_I	-0.3V	V _{REF} -0.1V	V _{REF} + 0.1V	3.6V	0.40V	V _{CCO} -0.40V	8	-8
HSTL15_II	-0.3V	V _{REF} -0.1V	V _{REF} + 0.1V	3.6V	NA	NA	NA	NA

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4.3.5 I/O Differential DC Characteristics

Table 4-12 I/O Differential DC Characteristics LVDS25

Name	Description	Condition	Min.	Тур.	Max.	Unit
V_{INA}, V_{INB}	Input Voltage		0	-	2.4	V
V_{CM}	Input Common Mode Voltage	Half the Sum of the Two Inputs	0.05	-	2.35	V
V_{THD}	Differential Input Threshold	Difference Between the Two Inputs	± 100	-	-	mV
I _{IN}	Input Current	Power On or Power Off	-	-	± 10	μΑ
V _{OH}	Output High Voltage for V_{OP} or V_{OM}	R _T = 100Ω	-	-	1.60	V
V _{OL}	Output Low Voltage for V_{OP} or V_{OM}	R _T = 100Ω	0.9	-	-	V
V _{OD}	Output Voltage Differential	$(V_{OP} - V_{OM}), R_T = 100\Omega$	250	350	450	mV
ΔV_{OD}	Change in V _{OD} Between High and Low		-	-	50	mV
Vos	Output Voltage Offset	$(V_{OP} + V_{OM})/2, R_T$ = 100 Ω	1.125	1.20	1.375	V
ΔV _{OS}	Change in V _{OS} Between High and Low		-	-	50	mV
Is	Short-circuit current	V _{OD} = 0V output short-circuit	-	-	15	mA

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4.4 AC Switching Characteristic

4.4.1 I/O Speed

Table 4-13 I/O Speed Parameters

Name	Description		Min	Max	Unit
f _{MAX}	Max. IO frequency GW1NS-2		-	150M	Hz
4	Mary LV/DC fraguesia	GW1NS-2	-	400M	Hz
T _{MAX_LVDS}	Max. LVDS frequency	GW1NS-4	-	750M	Hz

4.4.2 CFU Switching Characteristics

Table 4-14 CFU Block Internal Timing Parameters

Name	Description	Speed (Speed Grade		
Name	Description	Min	Max	- Unit	
t _{LUT4_CFU}	LUT4 delay	-	0.674	ns	
t _{LUT5_CFU}	LUT5 delay	-	1.388	ns	
t _{LUT6_CFU}	LUT6 delay	-	2.01	ns	
t _{LUT7_CFU}	LUT7 delay	-	2.632	ns	
t _{LUT8_CFU}	LUT8 delay	-	3.254	ns	
t _{SR_CFU}	Set/Reset to Register output	-	1.86	ns	
t _{CO_CFU}	Clock to Register output	-	0.76	ns	

4.4.3 External Switching Characteristics

Table 4-15 LUT External Switching Characteristics

Name	Description	Description Device		-5		-6	
ivame	Description	Device	Min	Max	Min	Max	Unit
Clocks	TBD	TBD	TBD	TBD	TBD	TBD	
Pin-LUT-Pin Delay	TBD	TBD	TBD	TBD	TBD	TBD	
General I/O Pin Parameters	TBD	TBD	TBD	TBD	TBD	TBD	

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4.4.4 Gearbox Internal Timing Parameters

Table 4-16 Gearbox Internal Timing Parameters

Name	Description	Тур.	Unit
FMAXIDDR	2:1 Gearbox maximum input frequency	410	MHz
FMAX _{IDES4}	4:1 Gearbox maximum input frequency	410	MHz
FMAX _{IDES8}	8:1 Gearbox maximum input frequency	410	MHz
FMAX _{IVIDEO}	7:1 Gearbox maximum input frequency	390	MHz
FMAX _{IDES10}	10:1 Gearbox maximum input frequency	410	MHz
FMAX _{IDES16}	16:1 Gearbox maximum input frequency	750	MHz
FMAX _{ODDR}	1:2 Gearbox maximum input frequency	355	MHz
FMAX _{OSER4}	1:4 Gearbox maximum input frequency	360	MHz
FMAX _{OSER8}	1:8 Gearbox maximum input frequency	355	MHz
FMAX _{OVIDEO}	1:7 Gearbox maximum input frequency	355	MHz
FMAX _{OSER10}	1:10 Gearbox maximum input frequency	355	MHz
FMAX _{OSER16}	1:16Gearbox maximum input frequency	750	MHz

4.4.5 B-SRAM Internal Timing Parameters

Table 4-17 B-SRAM Internal Timing Parameters

Name	Description		Speed	Grade	Unit
Ivairie	Description		Min	Max	Offic
t _{COAD_BSRAM}	Clock to output from read address/data		-	5.10	ns
t _{COOR_BSRAM}	Clock to output from output register		-	0.56	ns

4.4.6 DSP Internal Timing Parameters

Table 4-18 DSP Internal Timing Parameters

Name	Description	Speed Grade		Unit
name	Description	Min	Max	Offic
t _{COIR_DSP}	Clock to output from output register	-	4.80	ns
t _{COPR_DSP}	Clock to output from output register	-	2.40	ns
t _{COOR_DSP}	Clock to output from output register	-	0.84	ns

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4.4.7 On chip Oscillator Output Frequency

Table 4-19 On chip Oscillator Output Frequency

Name	Description		Min.	Тур.	Max.
	On chip Oscillator Output Frequency (0 ~ +85°C)	GW1NS-2	114MHz	120MHz	126MHz
	On chip Oscillator Output Frequency (-40 ~ +100°C)	GW1NS-2	108MHz	120MHz	132MHz
f _{MAX}	On chip Oscillator Output Frequency (0 ~ +85°C)	GW1NS-4	118.75MHz	125MHz	131.25MHz
	On chip Oscillator Output Frequency (-40 ~ +100°C)	GW1NS-4	112.5MHz	125MHz	137.5MHz
t _{DT}	Clock Duty Cycle		43%	50%	57%
t _{OPJIT}	Clock Period Jitter		0.01UIPP	0.012UIPP	0.02UIPP

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4.4.8 PLL Parameters

Table 4-20 PLL Parameters

Device	Speed Grade	Name	Min.	Max.
		CLKIN	3MHZ	400MHZ
	C7/I6	PFD	3MHZ	400MHZ
	C6/I5	VCO	400MHZ	1200MHZ
GW1NS-2/		CLKOUT	3.125MHZ	600MHZ
GW1NS-2C		CLKIN	3MHZ	320MHZ
	C5/I4	PFD	3MHZ	320MHZ
	C5/14	VCO	320MHZ	960MHZ
		CLKOUT	2.5MHZ	480MHZ
	C7/I6	CLKIN	3MHZ	400MHZ
		PFD	3MHZ	400MHZ
	C6/I5	VCO	400MHZ	1200MHZ
GW1NS-4/		CLKOUT	3.125MHZ	600MHZ
GW1NS-4C		CLKIN	3MHZ	320MHZ
	05/14	PFD	3MHZ	320MHZ
	C5/I4	VCO	320MHZ	960MHZ
		CLKOUT	2.5MHZ	480MHZ

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4.5 Cortex-M3 Electrical Specification

4.5.1 DC Characteristic

Table 4-21 Current Characteristic

Name	Description	Spec.	Unit	
ivame	Description	Min.	Max.	Utill
I _{VCC}	Max. current of VCC	-	100	mA
I _{VSS}	Max. current of VSS	-	≥100	mA
I _{INJ}	Leakage current	-	+/-5	mA

4.5.2 AC Characteristic

Table 4-22 Clock Parameters

Name	Description	Device	Spec.	Unit
			Min.	Max.
f _{HCLK} AHB clock frequency	GW1NS-2C	0	30	MHz
	And clock frequency	GW1NS-4C	0	80
f _{PCLK} APB clock frequency	GW1NS-2C	0	30	MHz
	APB Clock frequency	GW1NS-4C	0	80

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4.6 User Flash Characteristic (GW1NS-2C/2)

4.6.1 DC Characteristic

Table 4-23 GW1NS-2C/2 User Flash DC Characteristic

Name	Decemention	Spec.	11:4	
Name	Description	Min.	Max.	Unit
IVCC _{read}	V _{CC} read operation current	-	1.4	mA
IVCCX _{read}	V _{CCX} read operation current	-	0.6	mA
IVCC _{prog}	V _{CC} write operation current	-	0.2	mA
IVCCX _{prog}	V _{CCX} write operation current	-	2.2	mA
IVCC _{erase}	V _{CC} erase operation current	-	0.2	mA
IVCCX _{erase}	V _{CCX} erase operation current	-	2.3	mA
I _{IDLE-VCC}	V _{CC} IDLE current	-	10	uA
I _{IDLE-VCCX}	V _{CCX} IDLE current	-	100	uA
I _{LI}	Input leakage current	-	0.1	uA
I _{LO}	Output leakage current	-	0.1	uA
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Before setting configuration register.	1.14	1.26	V
V _{VREF}	After setting configuration register.	1.176	1.224	V
V	Before setting configuration register.	0.94	1.06	V
V _{VREF1V}	After setting configuration register.	0.97	1.03	V
V _{IL}	Input low level	-	0.1*V _{CC}	V
V _{IH}	Input high level	0.9*V _{CC}	-	V
V _{OL}	Output low level	-	0.1*V _{CC}	٧
V _{OH}	Output high level	0.9*V _{CC}	-	V
t _{PROG}	Write operation time	-	30	us
t _{SER}	Page erasure time	-	2	mA
t _{MER}	Macro erasure time	-	10	mA

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4.6.2 AC Characteristic

Table 4-24 GW1NS-2C/2 User Flash Timing Parameters

	_	Spec.	Spec.		
Name	Description	Min.	Max.	Unit	
tAS	Address set up time	2	-	ns	
tHS	Address hold-up time	2	-	ns	
tS	Write and erase setup time	5	-	ns	
tH	Write and erase hold time	5	-	ns	
tDS	Data set up time	5	-	ns	
tDH	Data hold-up time	5	-	ns	
tAC	Data read time	-	30	ns	
tACR	Data read time	-	80	ns	
tHZ	Time from high resistance to OE turning low	3	-	ns	
tAE	High-level time of AE	10	-	ns	
tAEL	Low-level time of AE	10	-	ns	
tAAD	Delay time from AE to AE during read operation	30	-	ns	
tAADR	Delay time from AE to AE in readback state	80	-	ns	
tTR	Time of TBIT rising edge after NVSTR rising edge	-	100	ns	
tTF	Time from NVSTR rising edge to IBIT falling edge during write operation		30	us	
tTF	Time from NVSTR rising edge to IBIT falling edge during page erasure operation	-	2	ms	
tTF	Time from NVSTR rising edge to IBIT falling edge during macro erasure operation	-	10	ms	
tNVSTRH	Hold time from NVSTR rising edge to AE rising edge	10	-	ns	
tNVSTRL	Hold time from NVSTR rising edge to IBIT falling edge	50	-	ns	
tCS	CS setup time	10	-	ns	
tRCH	CS hold-up time during read operation	0	-	ns	
tWCH	CS hold-up time during write operation	10	E	ns	
tECH	CS hold-up time during erasure operation	10	- 5	ns	
tDOH	Time from AE enabled to data output time	5	-	ns	
tOS	Read enable setup time	1	-	ns	

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tOH	Read enable hold-up time	30	-	ns
tOHR	Read enable hold-up time	80	-	ns

4.6.3 Operation Timing Diagrams

Figure 4-1 Read Mode

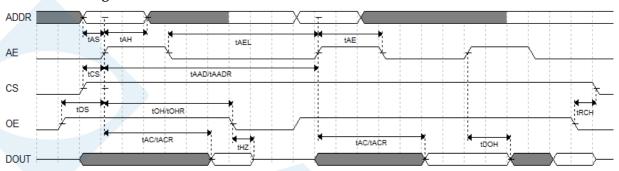


Figure 4-2 Write Mode

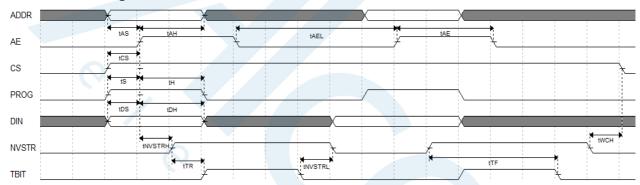
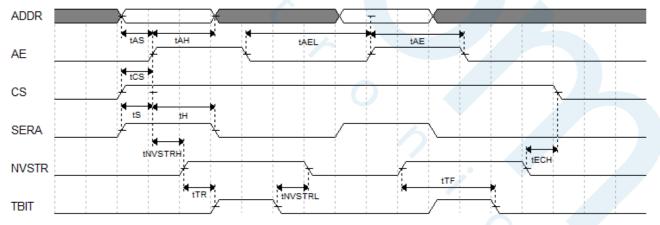


Figure 4-3 Page Erasure Mode



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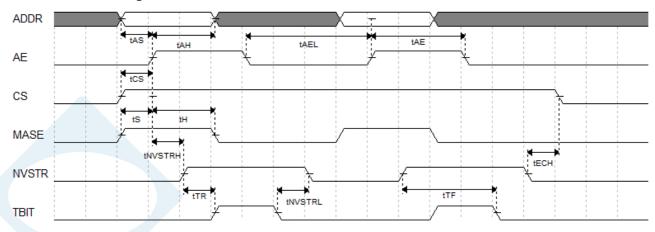


Figure 4-4 Module Rrasure Mode

4.7 User Flash Characteristic (GW1NS-4C/4)

4.7.1 DC Characteristics

Table 4-25 GW1NS-4/4C User Flash DC Characteristic

		•				
Name	Param-	Param- Max.		Unit	Wake-up	Condition
Ivaille	eter	V _{CC} ³	V _{CCX} Time	Condition		
Read mode (w/l 25ns) ¹		2.19	0.5	mA	NA	Min. Clcok period, duty cycle 100%, VIN = "1/0"
Write mode	l _{CC1} ²	0.1	12	mA	NA	
Erase mode	ICC1	0.1	12	mA	NA	
Page Erasure Mode		0.1	12	mA	NA	
Read mode static current (25-50ns)	I _{CC2}	980	25	μА	NA	XE=YE=SE="1", between T=Tacc and T=50ns, I/O=0mA; later than T=50ns, read mode is turned off, and I/O current is the current of standby mode.
Standby mode	I _{SB}	5.2	20	μA	0	V_{SS} , V_{CCX} , and V_{CC}

Note!

- [1] Means the average current, and the peak value is higher than the average one.
- [2] Calculated in different T_{new} clock periods.
 - T_{new}< T_{acc} is not allowed
 - $T_{now} = T_{acc}$
 - $T_{acc} < T_{new} 50ns: I_{CC1} (new) = (I_{CC1} I_{CC2})(T_{acc}/T_{new}) + I_{CC2}$
 - T_{new} >50ns: I_{CC1} (new) = (I_{CC1} I_{CC2})(T_{aco} / T_{new}) + 50ns x I_{CC2} / T_{new} + I_{SB}
 - t > 50ns, $I_{CC2} = I_{SB}$
- [3] VCC must be greater than 1.08V from the zero wake-up time.

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4.7.2 AC Characteristic

Table 4-26 GW1N-2/2B/4/4B/6/9 User Flash Timing Parameters

User Modes	Par	ameter	Name	Min.	Max.	Unit
	WC	:1		-	25	ns
	TC			-	22	ns
Access time ²	ВС		T _{acc} ³	-	21	ns
	LT			-	21	ns
	WC	;		-	25	ns
Program/Erase	Program/Erase to data storage			5	-	μs
Data storage h	old ti	me	T _{nvh}	5	-	μs
Data storage h	old ti	me (Overall erase)	T _{nvh1}	100	-	μs
Time from data	stor	age to program setup	T _{pgs}	10	-	μs
Program hold t	ime		T _{pgh}	20	-	ns
Write time			T_{prog}	8	16	μs
Write ready tim	ne		T _{wpr}	>0	-	ns
Erase hold time	е		T_{whd}	>0	-	ns
Time from control signal to write/Erase setup			T _{cps}	-10	-	ns
Time from SE t	Time from SE to read setup			0.1	-	ns
E pulse high le	vel ti	me	T _{pws}	5	-	ns
Adress/data se	tup t	ime	T _{ads}	20	-	ns
Adress/data ho	old tir	ne	T _{adh}	20	-	ns
Data hold-up ti	me		T _{dh}	0.5	-	ns
		WC1	T _{ah}	25	-	ns
Read mode		TC		22	_	ns
address hold		BC		21	-	ns
time ³		LT		21	-	ns
		WC		25	-	ns
SE pulse low le	evel t	ime	T _{nws}	2	-	ns
Recovery time			T _{rcv}	10	-	μs
Data storage ti	me		T_{hv}^{-4}	-	6	ms
Erasure time			T _{erase}	100	120	ms
Overall erase time			T _{me}	100	120	ms
Wake-up time from power down to standby mode			T _{wk_pd}	7	-	μs
Standby hold ti	ime		T _{sbh}	100	-	ns
V _{CC} setup time			T _{ps}	0	S	ns
V _{CCX} hold time			T_{ph}	0	-	ns

Note!

• [1] The parameter values may change;

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- [2] The values are simulation data only.
- [3]After XADR, YADR, XE, and YE are valid, T_{acc} start time is SE rising edge. DOUT
 is kept until the next valid read operation;
- [4]T_{hv} is the time between write and the next erasure. The same address can not be written twice before erasure, so does the same register. This limitation is for safety;
- [5]Both the rising edge time and falling edge time for all waveform is 1ns;
- [6] TX, YADR, XE, and YE hold time need to be T_{acc} at leaset, and T_{acc} start from SE rising edge.

4.7.3 Operation Timing Diagrams

Figure 4-5 User Flash Read Operation

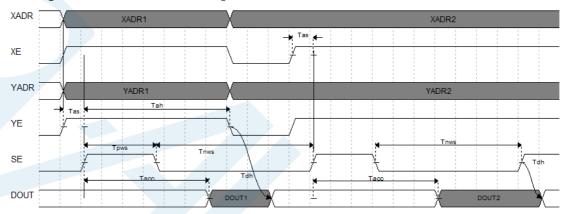
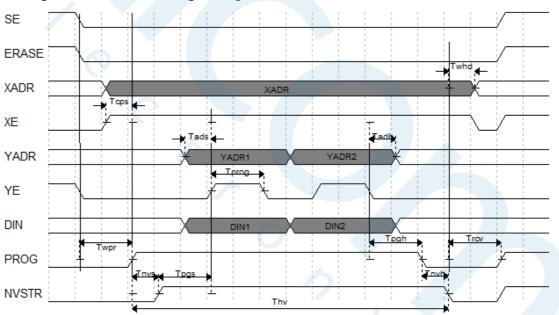


Figure 4-6 User Flash Program Operation



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4 AC/DC Characteristic 4.8 ADC Characteristics

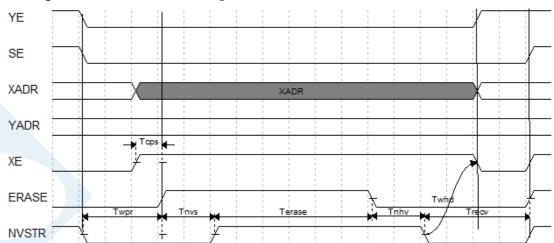


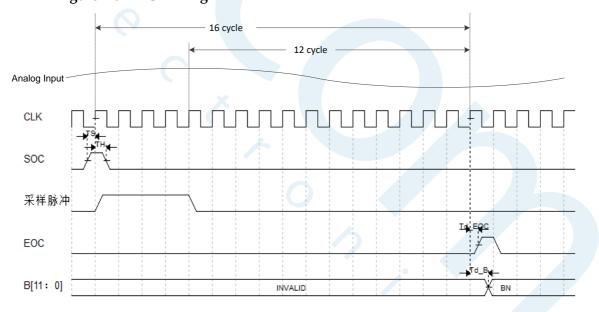
Figure 4-7 User Flash Erase Operation

4.8 ADC Characteristics

4.8.1 ADC Timing

In total, 16 clock cycles are needed for ADC to sample analog input signals and convert them to output digital signals. The first four clock cycles are used to sample and hold; the latter twelve clock cycles are used for the SAR algorithm to generate the required output signals. If the ECO signal becomes high at the 16th clock cycle, the conversion is complete, and the converted digital data will output at the EOC rising edge.

Figure 4-8 ADC Timing



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4 AC/DC Characteristic 4.8 ADC Characteristics

Table 4-27 ADC Timing Parameters

Name	Description	Spec.		Unit	
Name	Description	Min.	Max.	Offic	
CLK	Clock cycle	62.5	-	ns	
Ts	SoC setup time	0	-	ns	
T _H	SoC hold-up time	10	-	ns	
T _{D_EOC}	EOC delay time	-	13.5	ns	
T _{D_B}	Data-out delay time	-	16	ns	

4.8.2 Electrical Characteristic Parameters

Table 4-28 ADC Parameters

Danasatan	Description	Spec.			11.24
Parameter	Description	Min.	Тур.	Max.	Unit
DC Precision					
0	Data output bits		12		bit
INL	Integral nonlinearity		+/- 0.84		LSB
DNL	Differential nonlinearity		+/- 0.46		LSB
Offset error	Offset error		0.45		%FS
Gain error	Gain error		0.02		%FS
Analog Input					
CH[7: 0]	Single-ended input range	0.01*VREF		0.99*VRE F	V
CIN	Input capacitance		11.52		pF
Slew Rate					
SoC	Sample frequency			1	MHz
CLK	Main clock			16	MHz
Date-out delay	Date-out delay		12		Clock cycle
Dynamic Chara	cteristic Parameters				
SINAD	Signal Noise Ratio		64.8(Fin=1.47K)		DB
SINAD	Signal Noise Kallo		62.6(Fin=107K)		DB
SFDR	Spurious-free		84.9(Fin=1.47K)		DB
SFDR	dynamic range		81.7(Fin=107K)		DB
HD2	Second harmonic		-104(Fin=1.47K)		DB
1102	distortion		-87.1(Fin=107K)		DB
HD3	Third harmonic		-94.1(Fin=1.47K)		DB
1103	distortion		-80.6(Fin=107K)	J	DB
THD	Total harmonic		-87.2(Fin=1.47K)		DB
1110	distortion (Fifth)		-79.3(Fin=107K)		DB

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Dovomotov	Description	Spec.			- Unit
Parameter	Description	Min.	Тур.	Max.	Unit
ENOB	Valid data-out bits		10.5(Fin=1.47K)		bit
ENOB	valid data-out bits		10.1(Fin=107K)		bit
Reference Volta	age				
VREF	Reference Voltage	0.5*V _{CCO0}		V_{CCO0}	V
Digital Input					
V _{IH}	Input high level	0.7*V _{CC}	V _{CC}		V
V _{IL}	Input low level		0	0.3*V _{CC}	V
Digital output B	[11: 0]				
V _{OH}	Output high level	0.7*V _{CC}			V
V _{OL}	Output low level			0.3*V _{CC}	V
Supply voltage					·
V _{CCO0}	Analog/digital voltage	2.97	3.3	3.63	V
V _{CC}	Digital voltage	1.08	1.2	1.32	V
I _{vccoo}	Analog/digital current		750(Fin=107K)		uA
I _{vcc}	Digital current		4(Fin=107K)		uA
I _{pd}	Turning off current		0.15		mA

4.9 Configuration Interface Timing Specification

The GW1NS series of FPGA products GowinCONFIG support six configuration modes: AUTO BOOT, SSPI, MSPI, DUAL BOOT, SERIAL, and CPU. Users can configure the mode value to select the required programming mode. For detailed information, please refer to UG290, User Guide.

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5 Ordering Information 5.1 Part Name

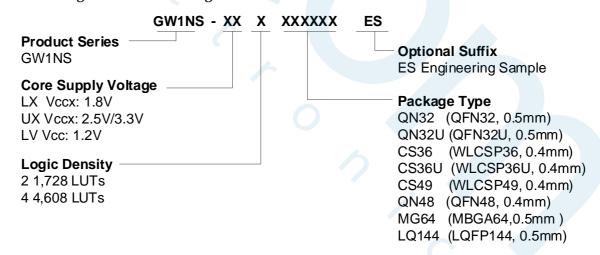
5Ordering Information

5.1 Part Name

Note!

- Speed grade is used for LX, UX, and LV devices.
- For further information about package type and pin number, please refer to <u>2.2 Product Resources</u> and <u>2.3 Package Information</u>.
- The LittleBee[®] family devices and Arora family devices of the same speed level have different speed.
- Both "C" and "I" are used in GOWIN part name marking for one device. GOWIN devices are screened using industrial standards, so one same device can be used for both industrial (I) and commercial (C) applications. The maximum temperature of the industrial grade is 100°C, and the maximum temperature of the commercial grade is 85°C. Therefore, if the same chip meets the speed level 7 in the commercial grade application, the speed level is 6 in the industrial grade application.

Figure 5-1 Part Naming-ES



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5 Ordering Information 5.1 Part Name

Figure 5-2 Part Naming-ES (With Cortex-M3)

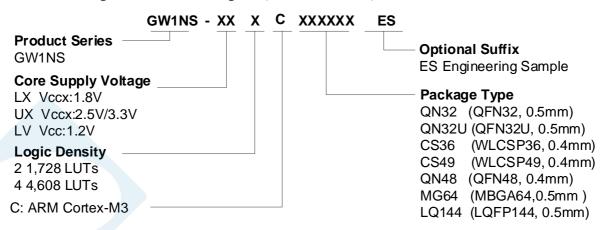


Figure 5-3 Part Naming-Production

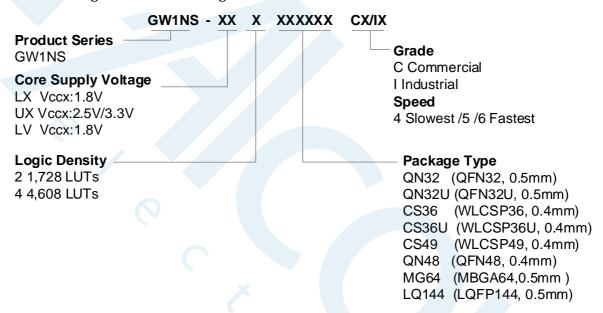
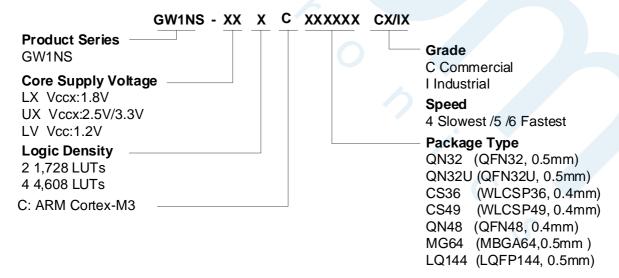


Figure 5-4 Part Naming-Production (With Cortex-M3)



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5.2 Package Mark Example

The device information of GOWINSEMI is marked on the chip surface, as shown in Figure 5-5.

Figure 5-5 Package Mark Example

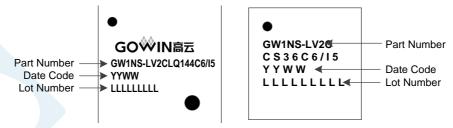


图 5-6 GW1NS-2C Package Mark Example



图 5-7 GW1NS-4 Package Mark Example

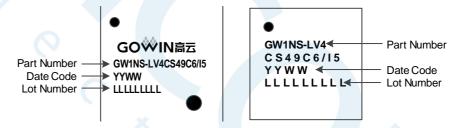
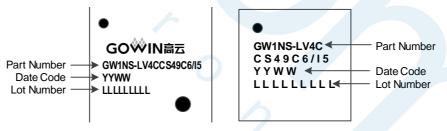


图 5-8 GW1NS-4C Package Mark Example



Note!

The first two lines in the right figure above are the "Part Number".

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